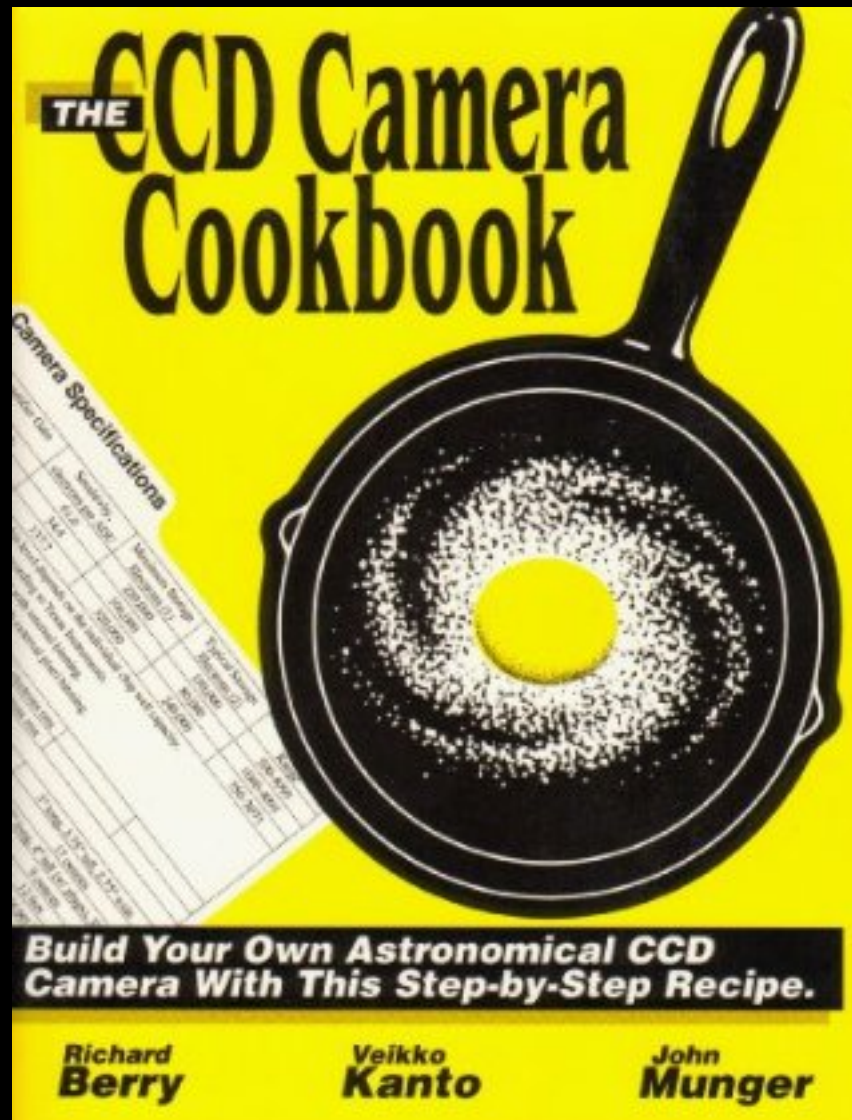


Topic 2: Detectors



Arne Henden
Director, AAVSO
arne@aavso.org





Do-it-yourself CCD camera; 1990's

Other 1990's cameras

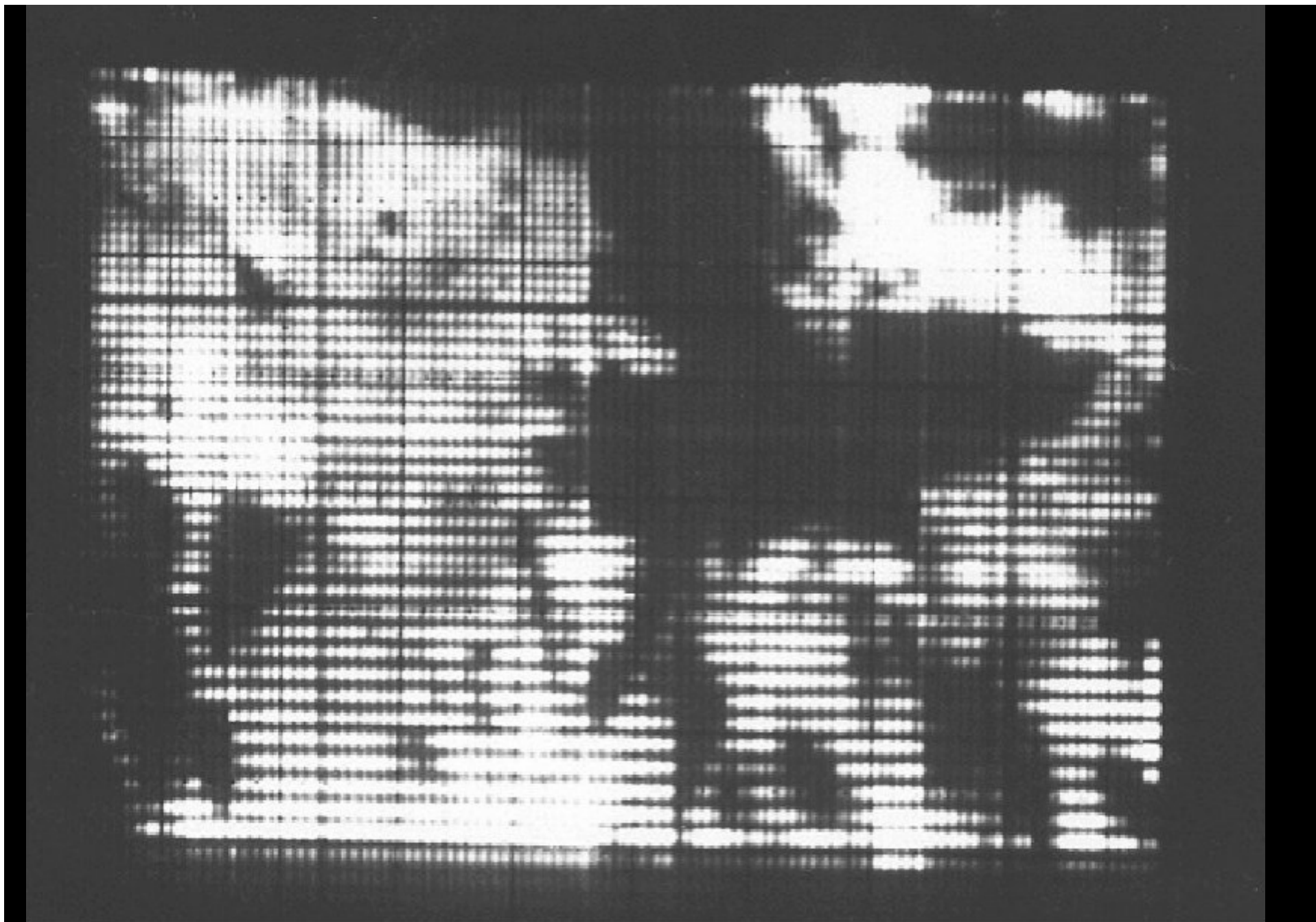
- Spectrasource Lynxx, HPC-1
- SBIG ST-4, ST-6
- Meade Pictor

Sensor types

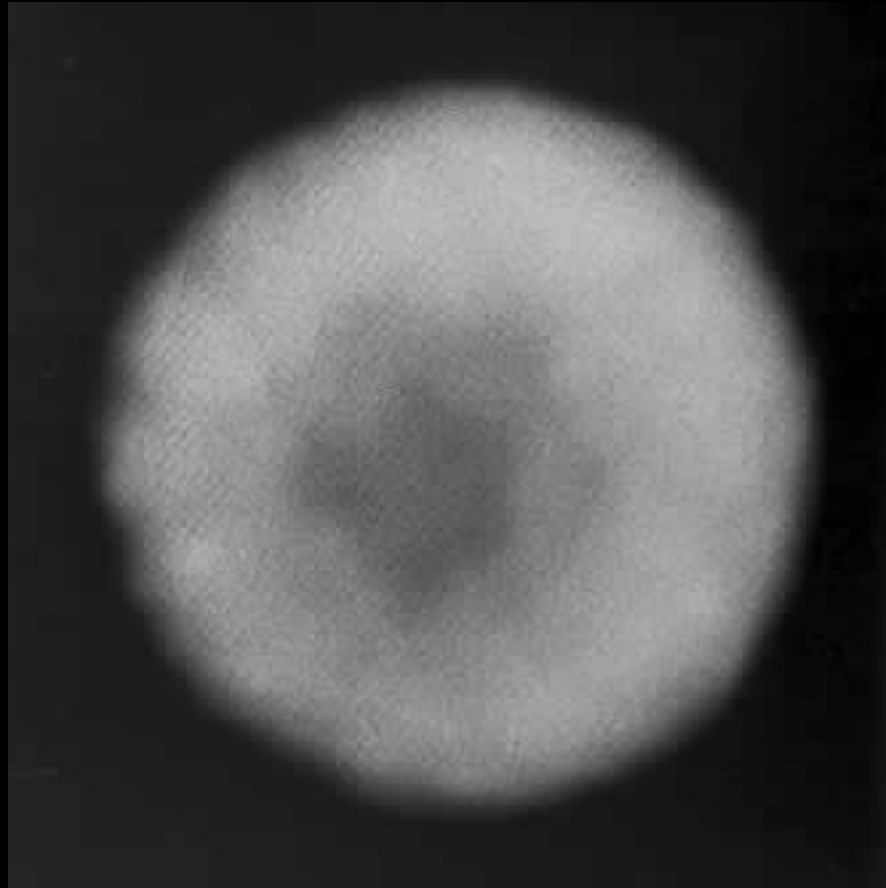
- Charge-Coupled Device (CCD)
 - Full-frame
 - Interline transfer
 - Electron-multiplying
- CMOS
- Hybrid

CCD Sensors

- Invented 1969 Smith&Boyle, Bell Telephone Laboratories
- First used by Jim Janesick 1974 (8" telescope, 100x100 array)
- First professional published image by Brad Smith (Uranus, 1976)
- TI 800x800 for HST proposed in 1976



Moon, Janesick 1974



Uranus (1976, B. Smith; pole-on)

Sensor vendors

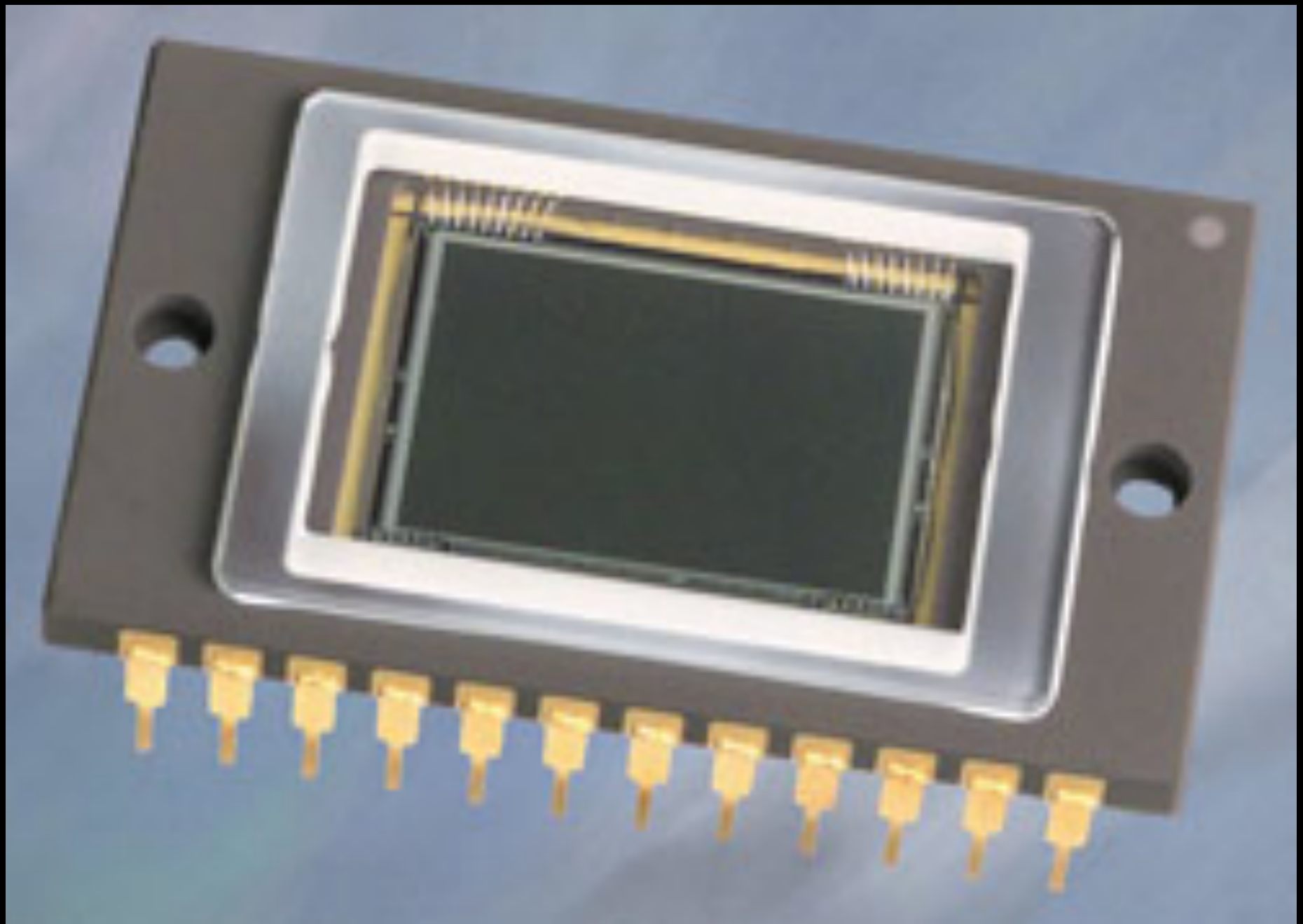
- Texas Instruments
- Kodak
- Sony (Hole Accumulation Device)
- E2V
- STA
- Fairchild/Loral
- Foveon

Kodak

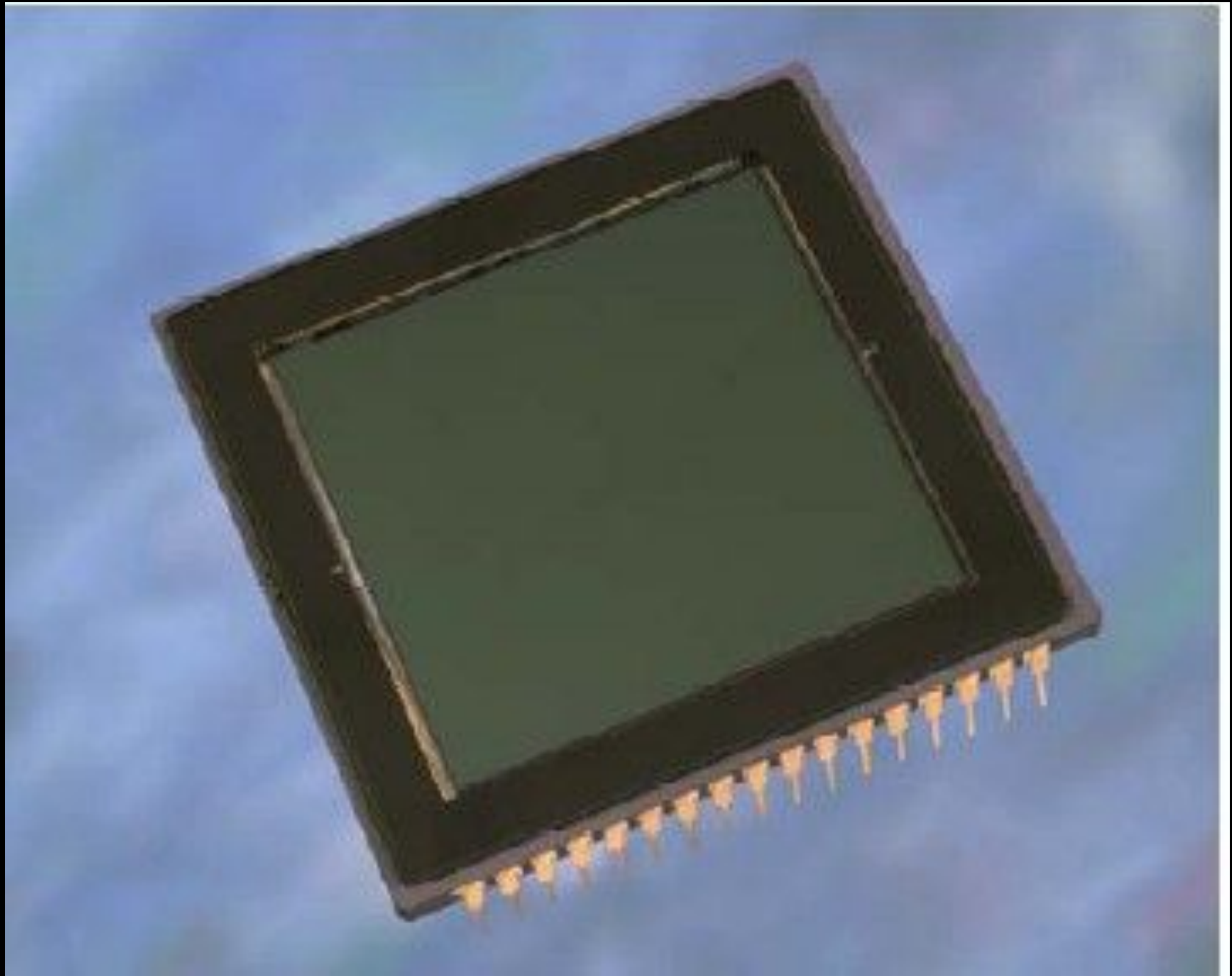
- Now Truesense Imaging
 - <http://www.truesenseimaging.com>
- Naming convention
 - KA + F(ullframe)/I(nterline) + Mpix + version
- KAF-0400 (0.4Mpix, 00 version)
- KAF-16803 (16.8Mpix, 03 version)
- KAI-29050 (Interline, 29.0Mpix, 50ver)

Sensor grading/classes

- Point defect
 - Dark pixel $> 6\%$ weak
 - Bright (hot) pixel $\sim 4000e^-/\text{pix}/\text{sec}$
- Cluster defect. Grouping of not more than 5 adjacent point defects
- Column defect. >5 contiguous point defects or a hot pixel along a column
- Defects are usually outside of central zone
- Most commercial sensors grade 0(best)-2(worst)
- Engineering grade sensors sometimes available



KAF-3200 in DIP package



KAF-16803



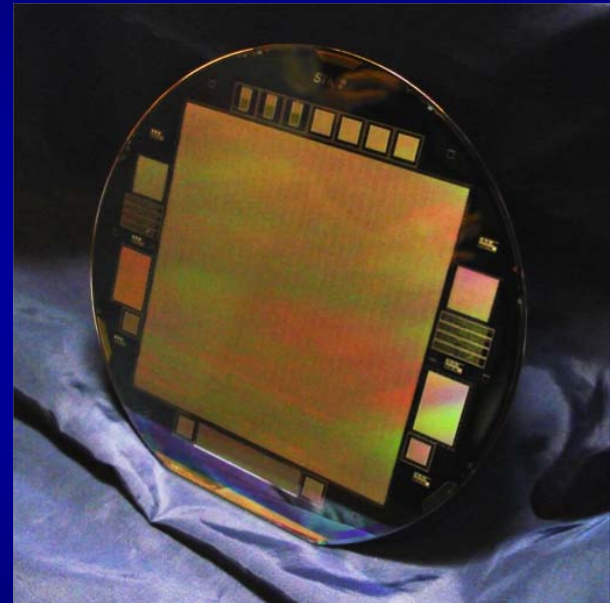
KAF-50100

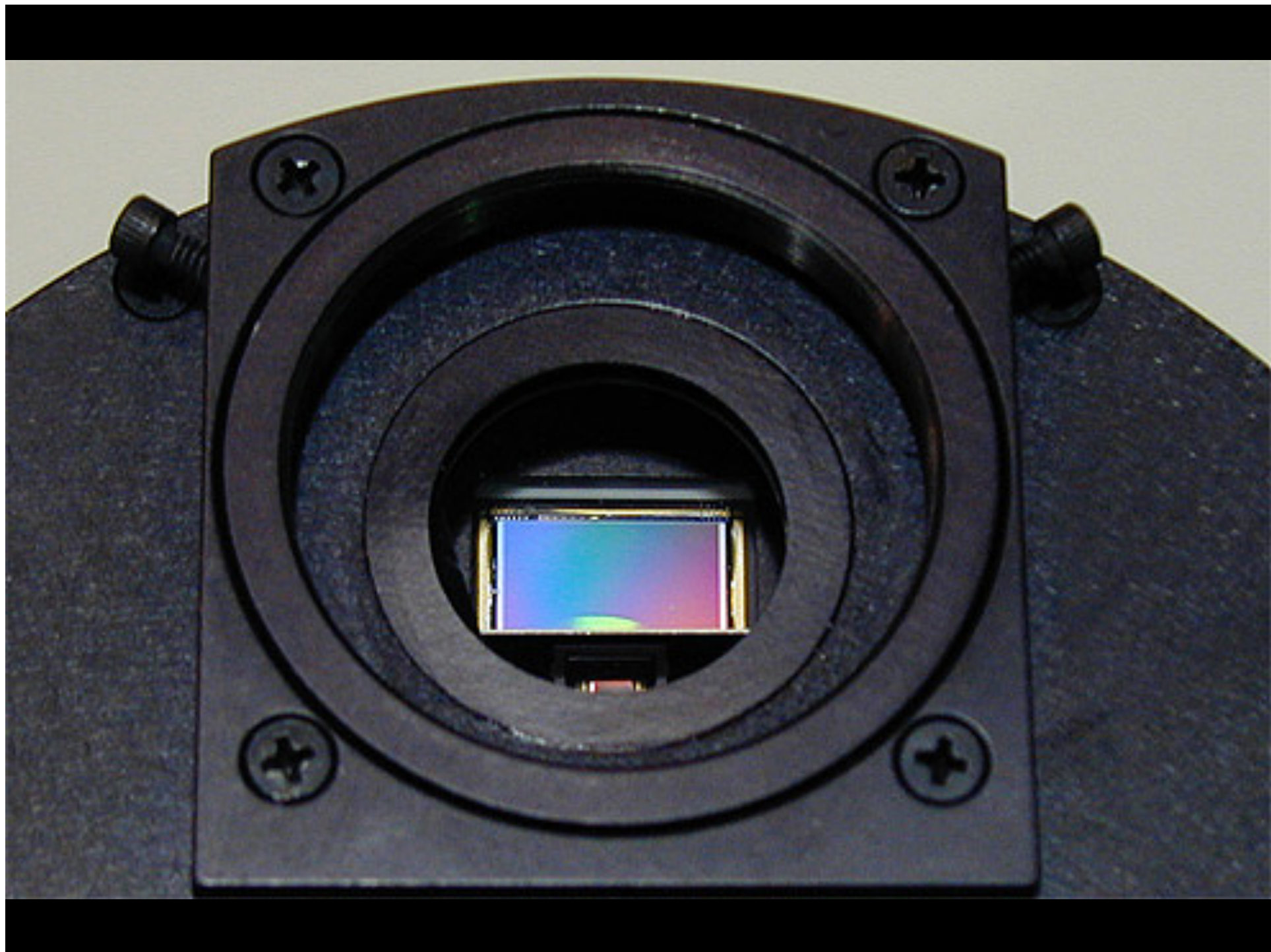


STA1600B 111Mega pixel imager



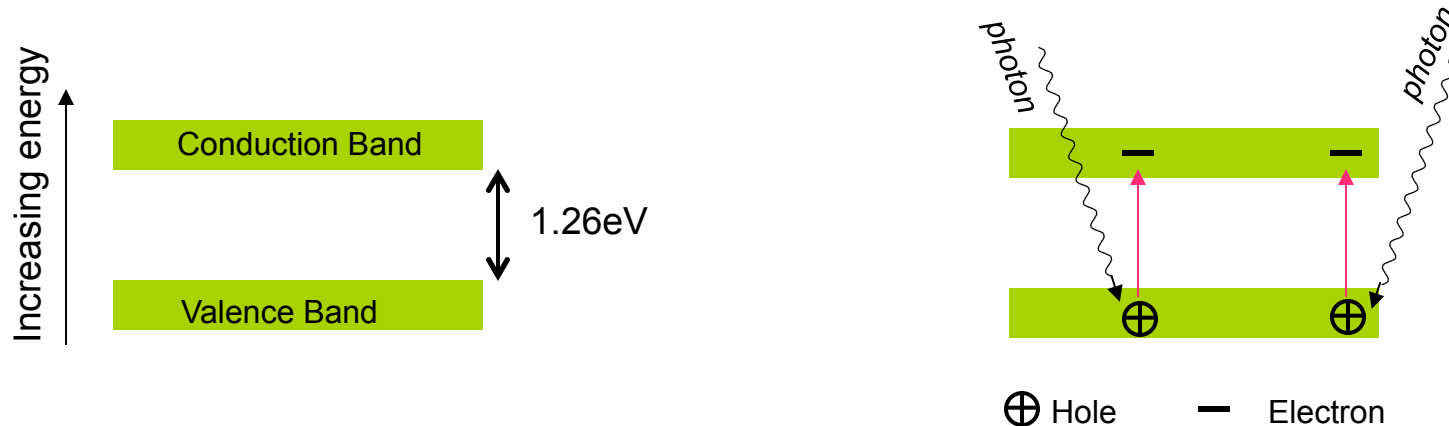
- Full 6" wafer imager
- 10560 x 10560 pixels
- 9 micron pixel
- 111,513,600 pixels per frame
- 16 dual stage high speed outputs
- Backside thinned available
- Acquisition speeds up to 1 frame/sec
- Designed for US Naval Observatory





Photoelectric Effect.

The effect is fundamental to the operation of a CCD. Atoms in a silicon crystal have electrons arranged in discrete energy bands. The lower energy band is called the Valence Band, the upper band is the Conduction Band. Most of the electrons occupy the Valence band but can be excited into the conduction band by heating or by the absorption of a photon. The energy required for this transition is 1.26 electron volts. Once in this conduction band the electron is free to move about in the lattice of the silicon crystal. It leaves behind a 'hole' in the valence band which acts like a positively charged carrier. In the absence of an external electric field the hole and electron will quickly re-combine and be lost. In a CCD an electric field is introduced to sweep these charge carriers apart and prevent recombination.



Thermally generated electrons are indistinguishable from photo-generated electrons. They constitute a noise source known as 'Dark Current' and it is important that CCDs are kept cold to reduce their number.

1.26eV corresponds to the energy of light with a wavelength of $1\mu\text{m}$. Beyond this wavelength silicon becomes transparent and CCDs constructed from silicon become insensitive.

Sensitivity

- Silicon cutoff wavelength = $1239/E(\text{eV})$
- For 1.14eV, $\lambda = 1086.8\text{nm}$
- Silicon is transparent in infrared (good lens!)
- 1.2-3.1eV get one electron-hole pair (1086-400nm)
- Can cover 1.1eV-10keV (0.1nm)

Other material

- Germanium 0.66eV bandgap; 1600nm
- However, germanium oxide not good insulator; hard to make germanium CCDs
- Other materials usually manufactured as hybrid detectors

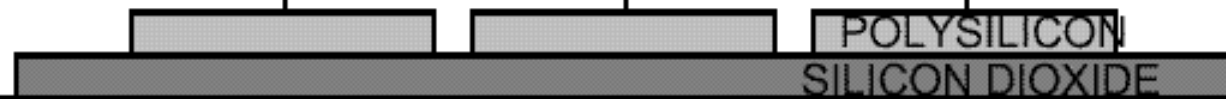
INCIDENT LIGHT



-V

+V

-V



POLYSILICON

SILICON DIOXIDE

POTENTIAL
BARRIER

POTENTIAL
BARRIER

POTENTIAL
WELL

PHOTOGENERATED
ELECTRONS

SILICON SUBSTRATE



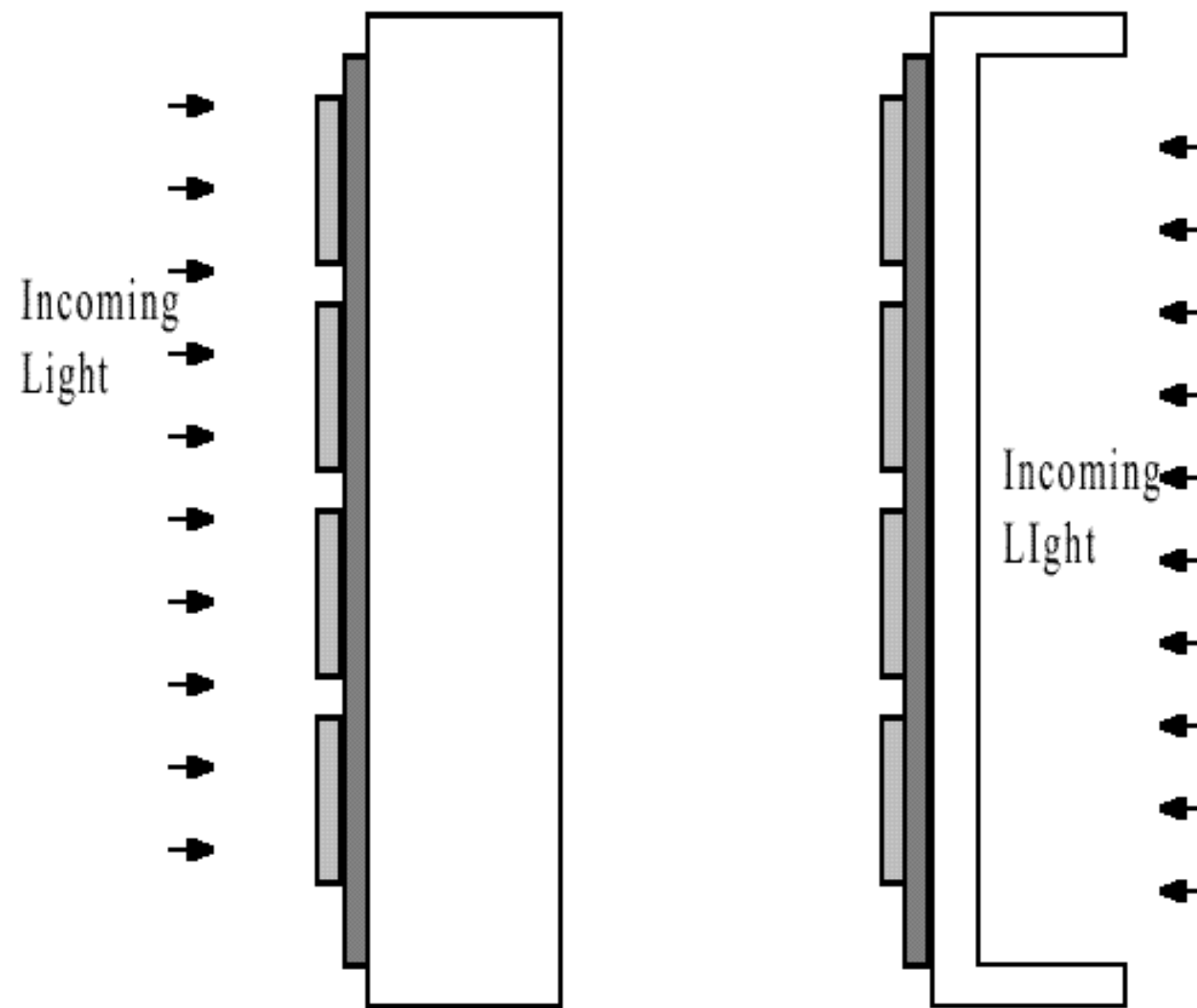


Figure 20: Thick and Thinned CCD

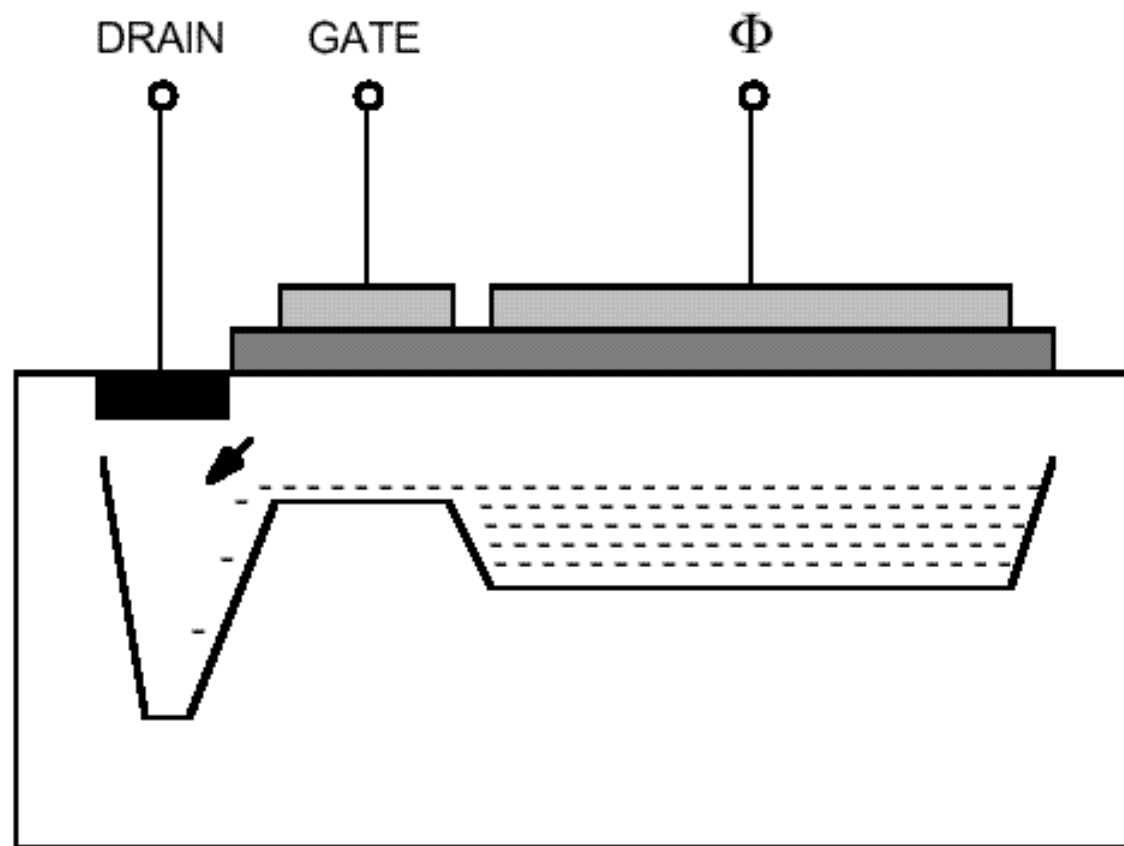
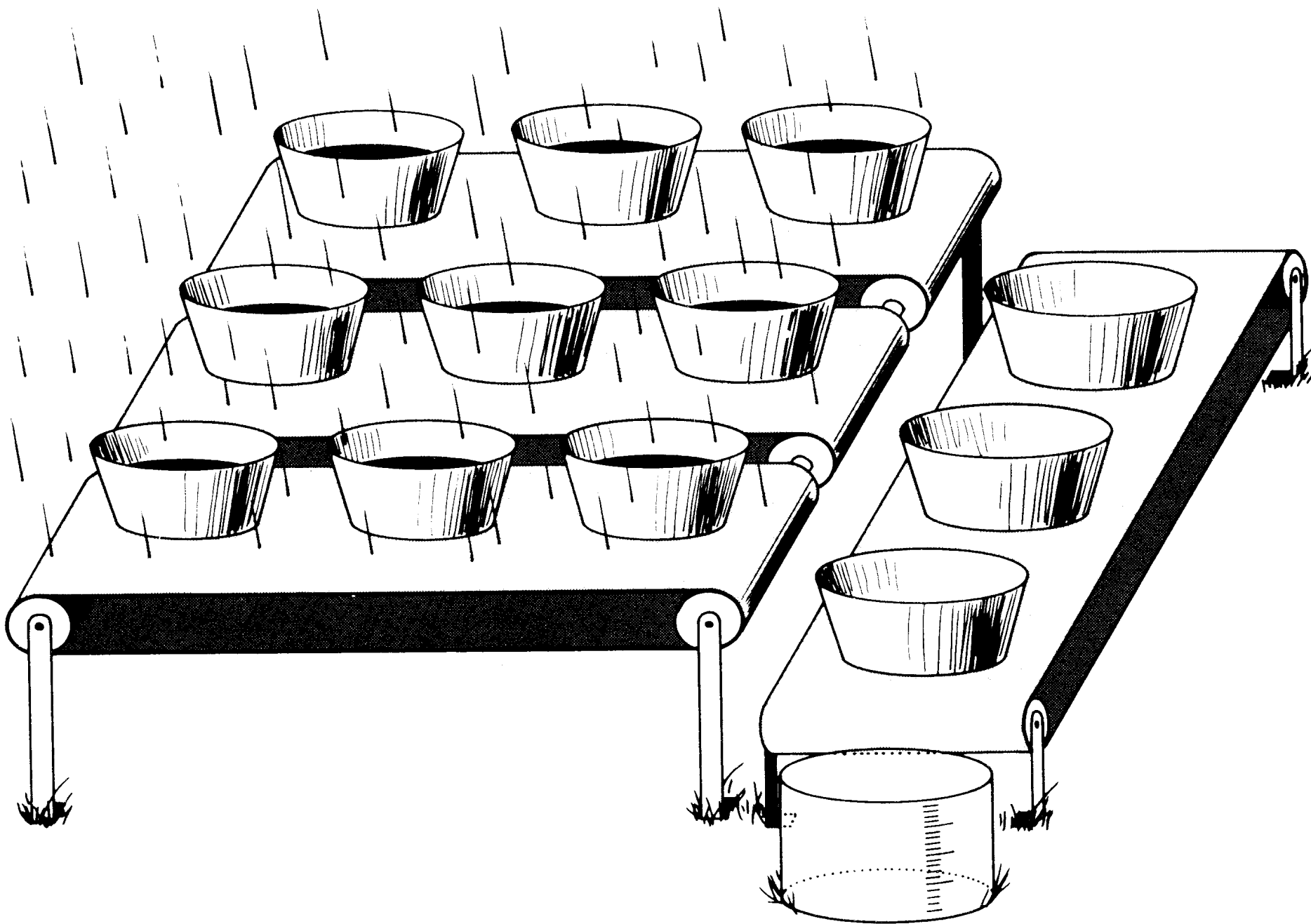
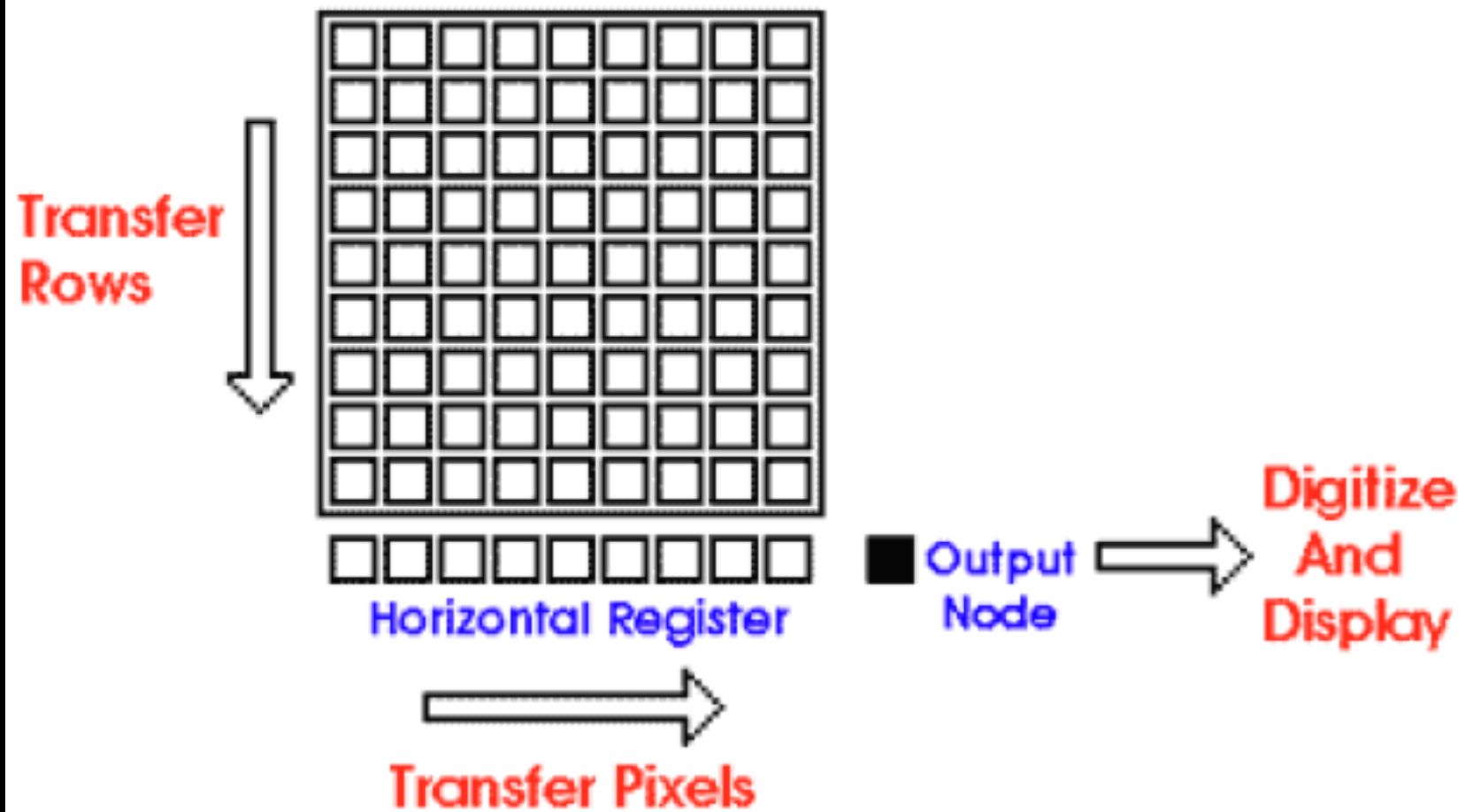
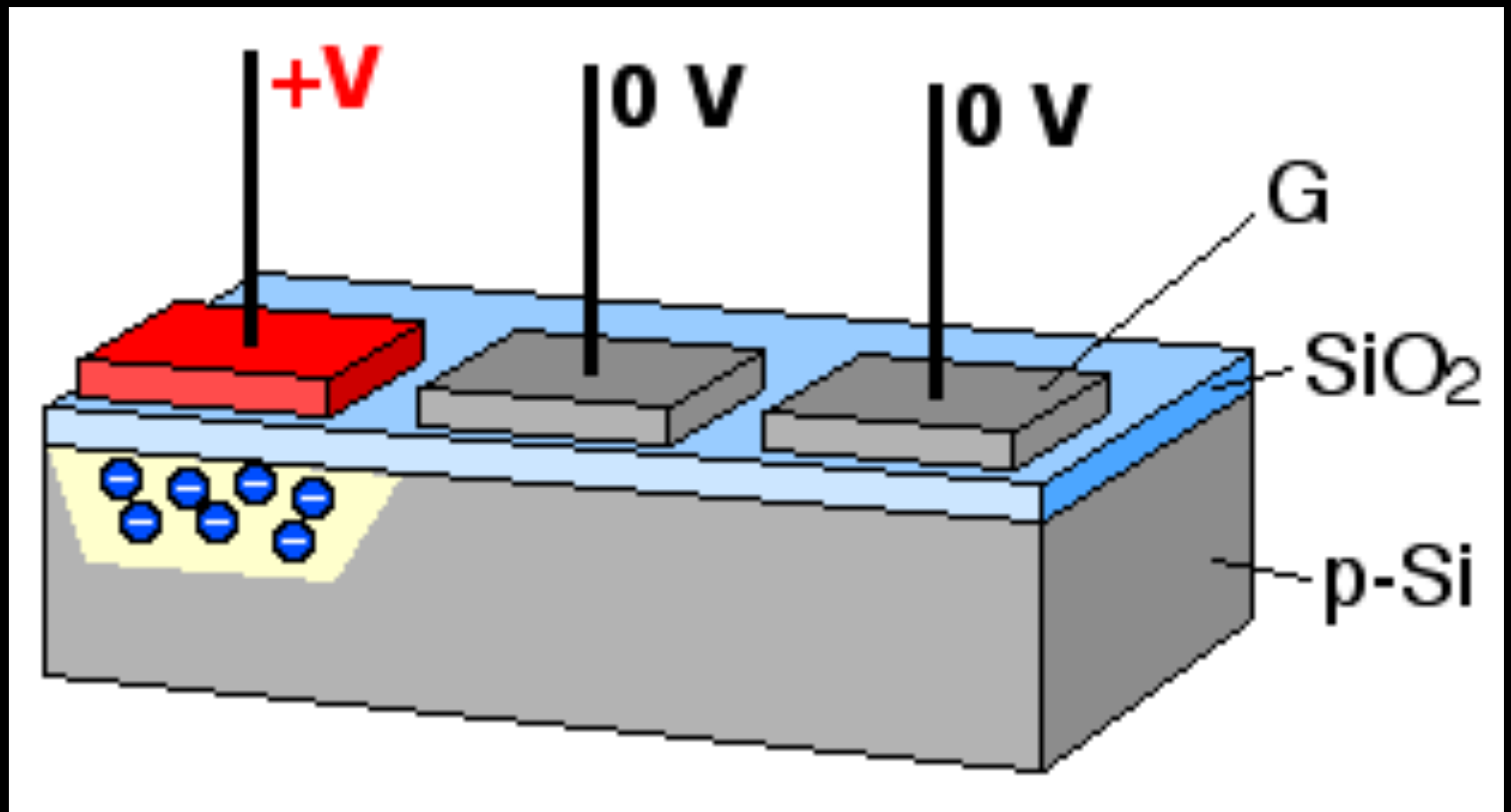


Figure 19: Lateral Overflow Drain

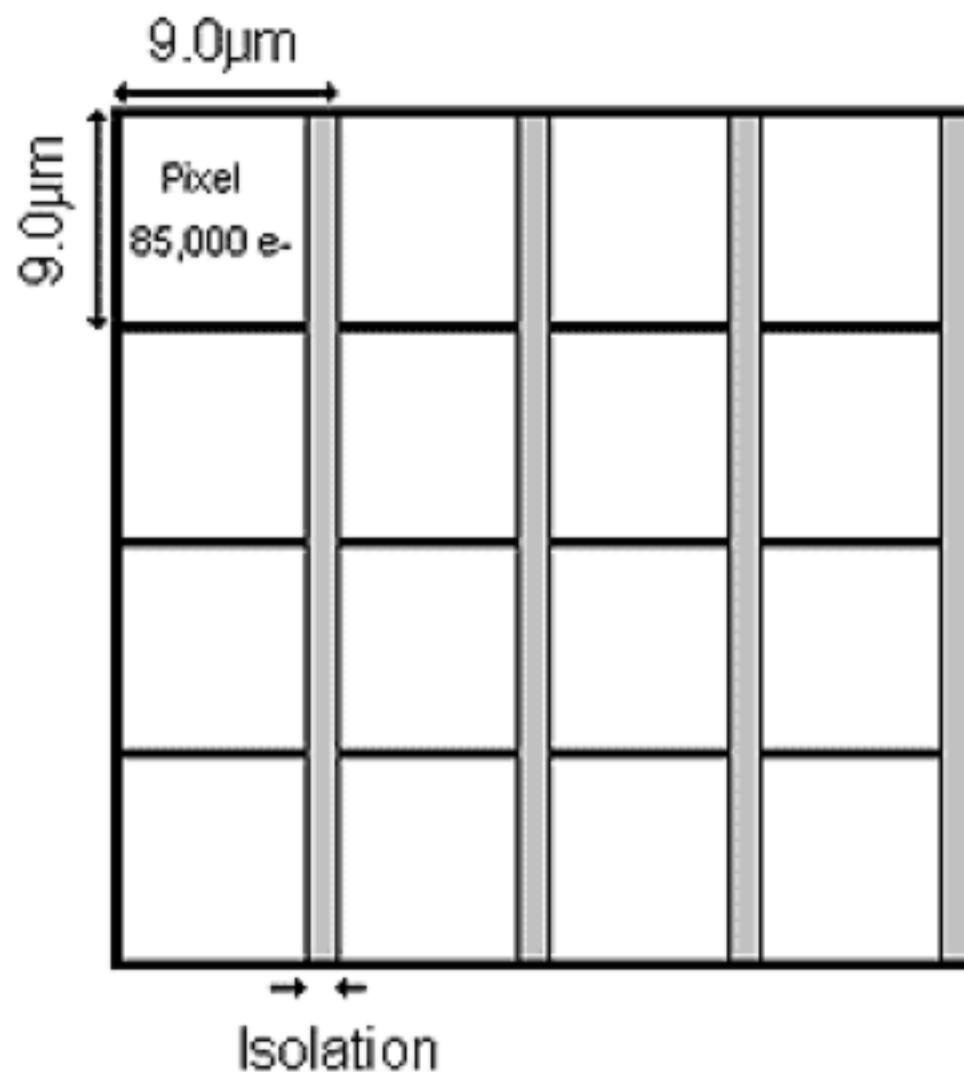




CCD charge transfer



Credit: Schmid



No Anti-Blooming Gate

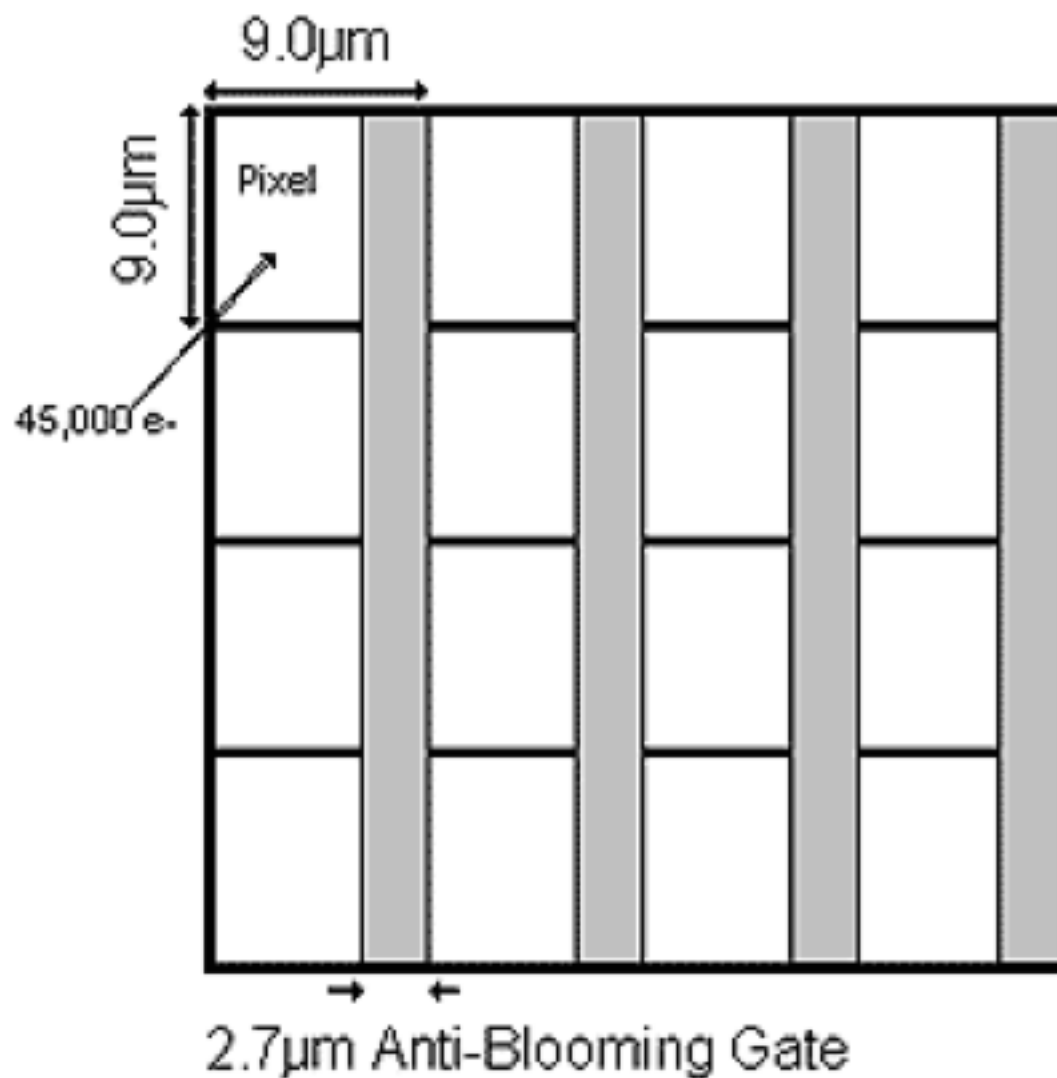
100% Fill Factor

85,000 electron well depth

Higher Quantum Efficiency

Blooming (Streaking) possible

NABG pixel shape



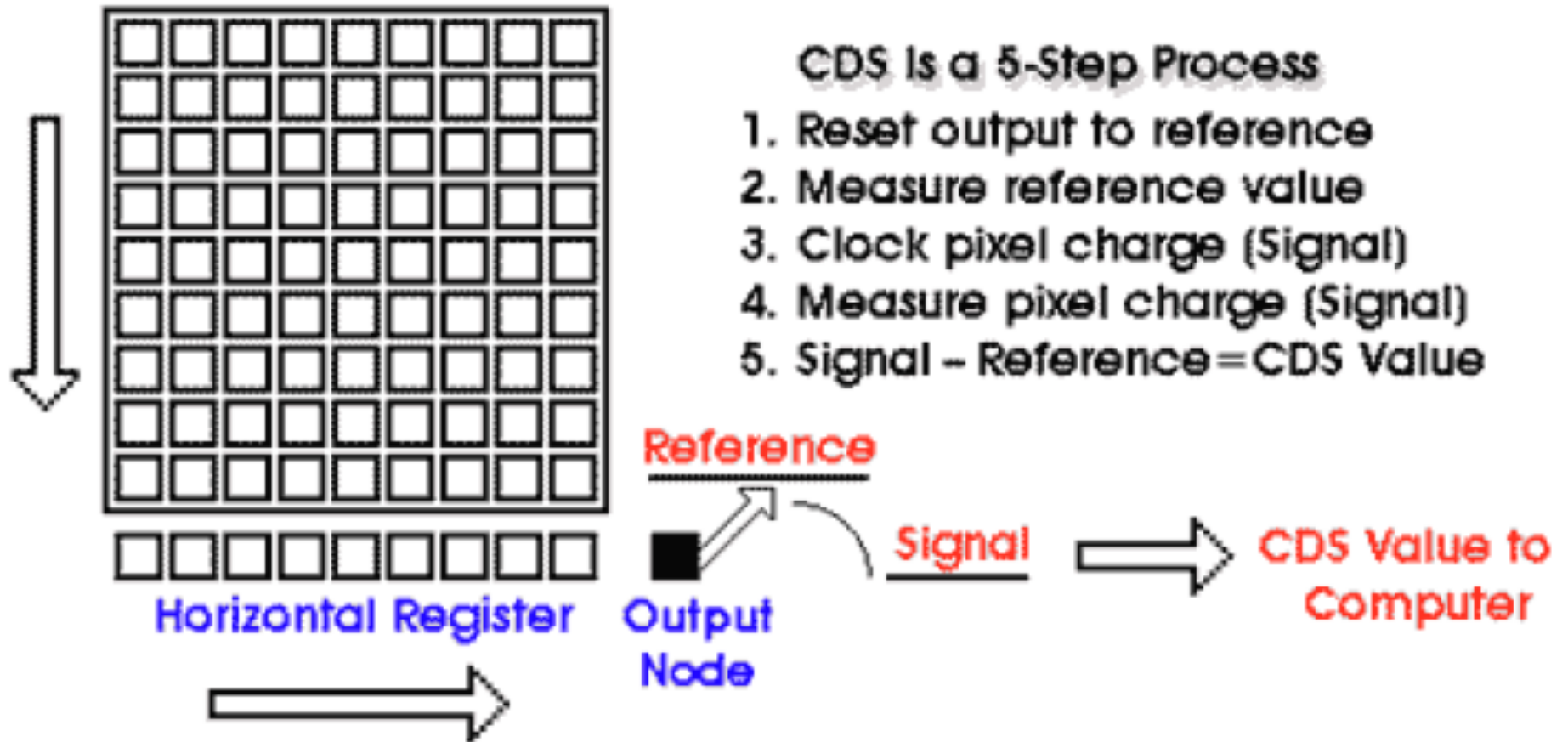
Anti-Blooming Gate

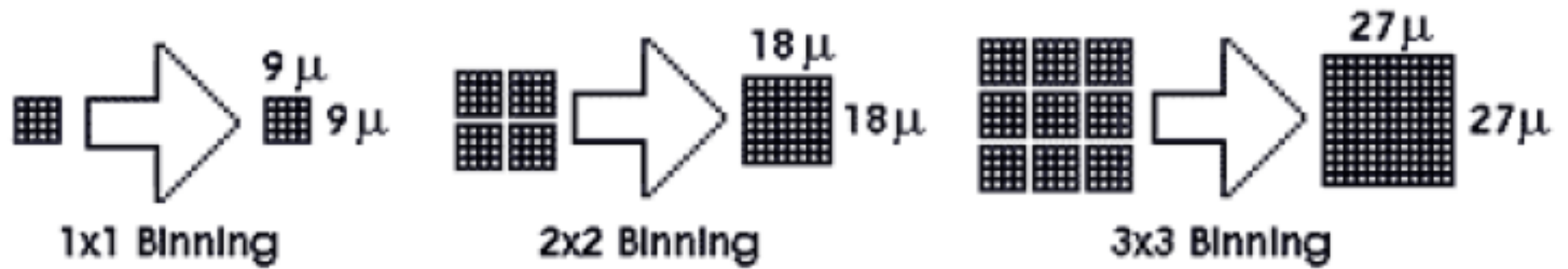
70% Fill Factor

45,000 electron well depth

Lower Quantum Efficiency

ABG pixel shape





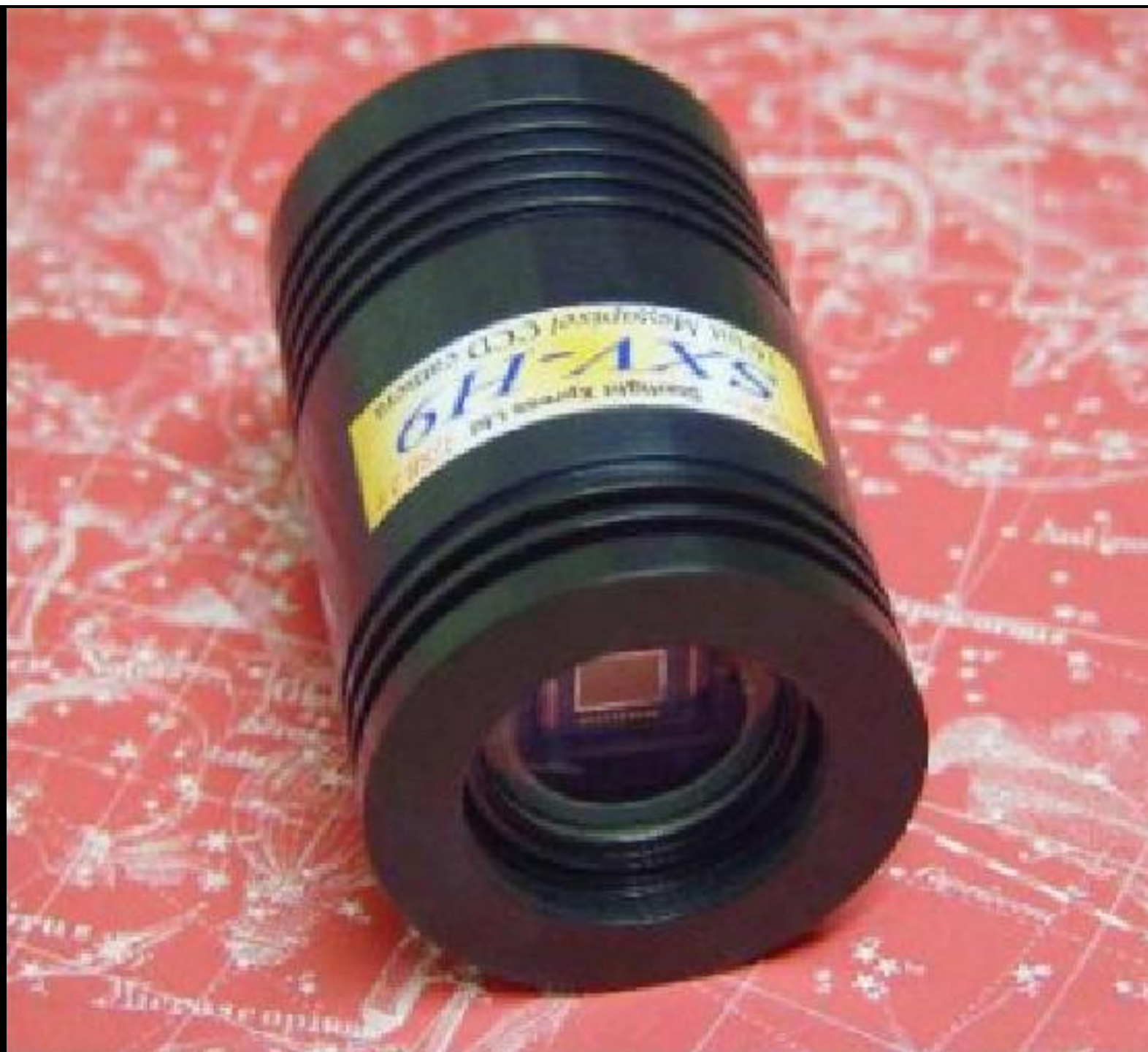
Binning example

Camera types

- Monochrome science
- One-shot color
- DSLR
- webcam









Starlight Xpress

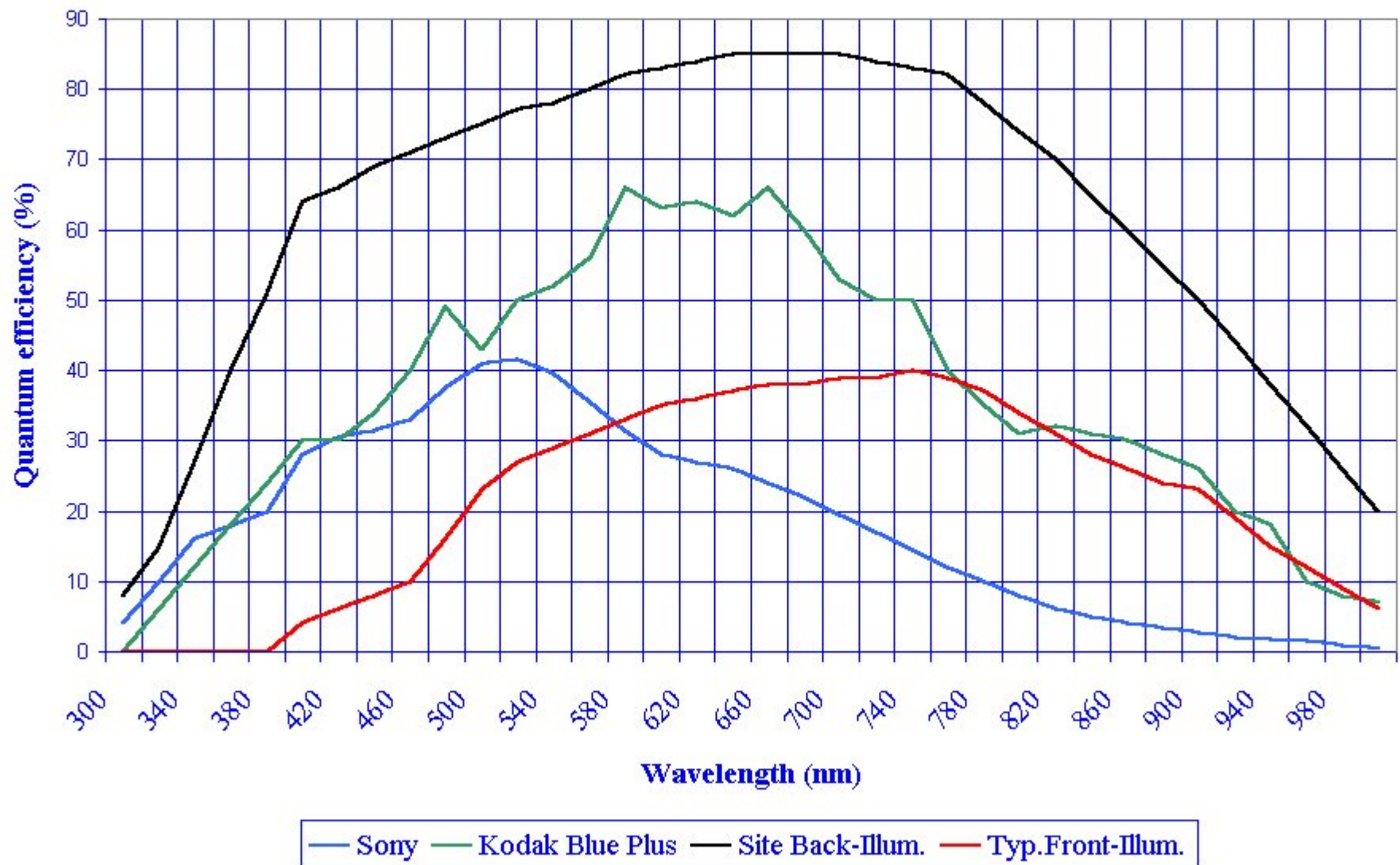


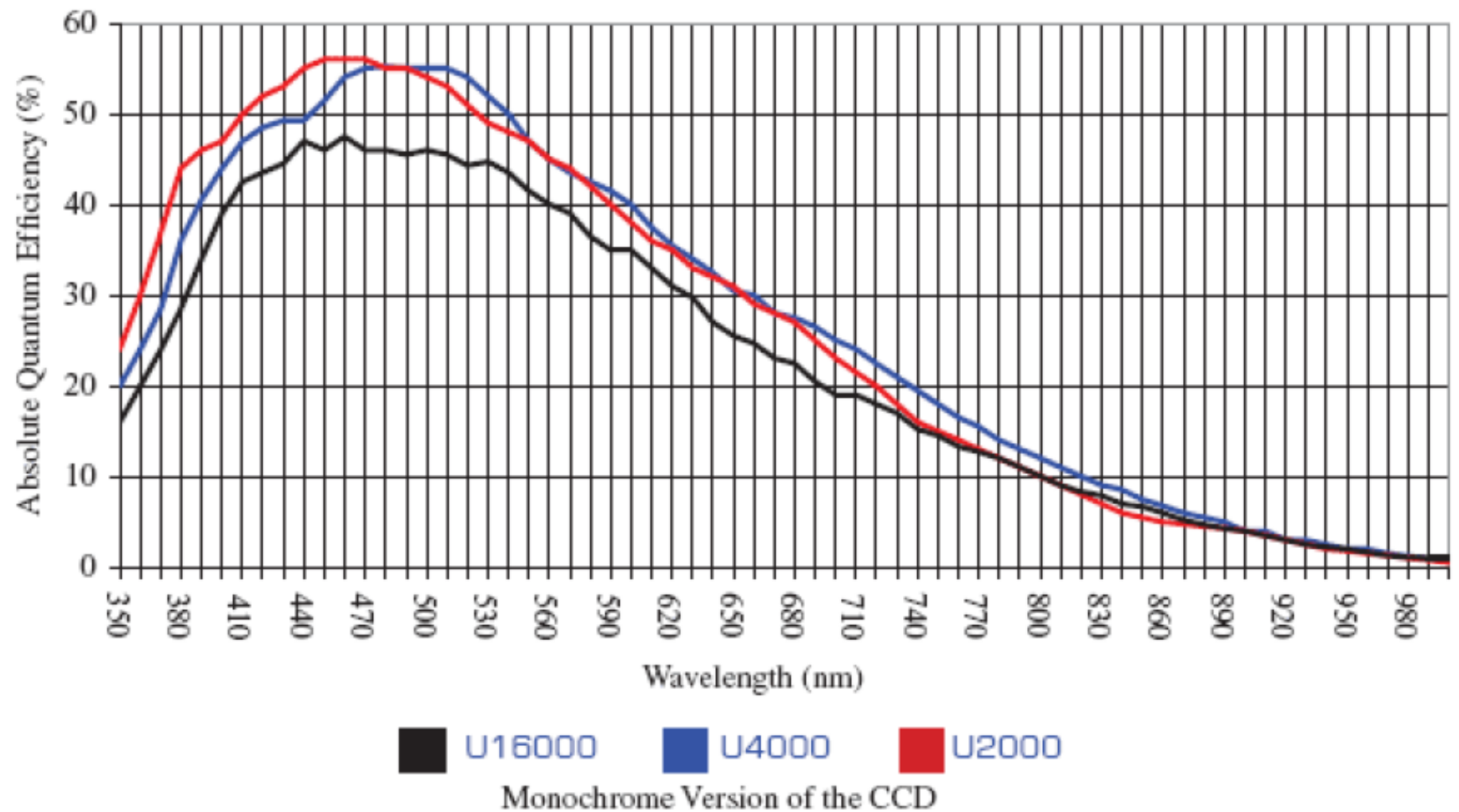
Typical Apogee camera D7 body



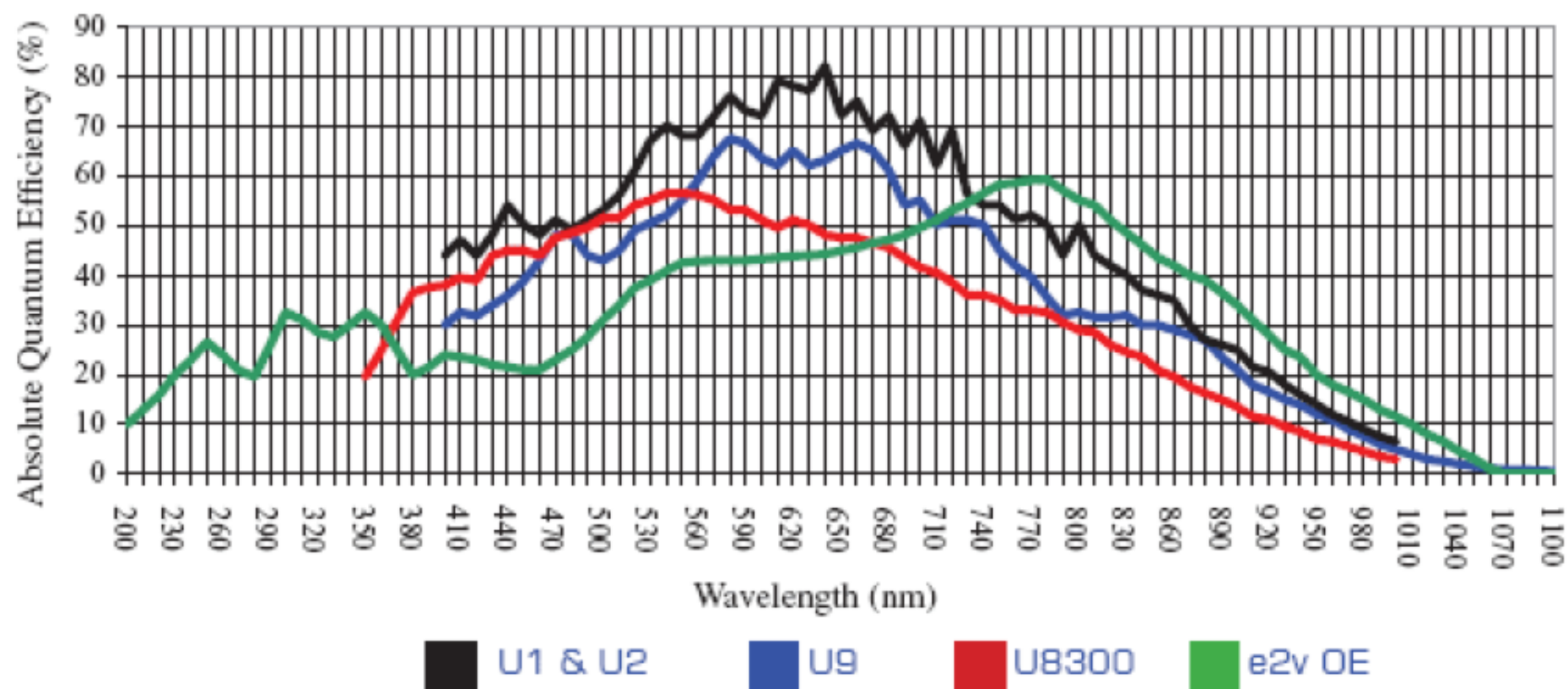


CCD Sensitivity

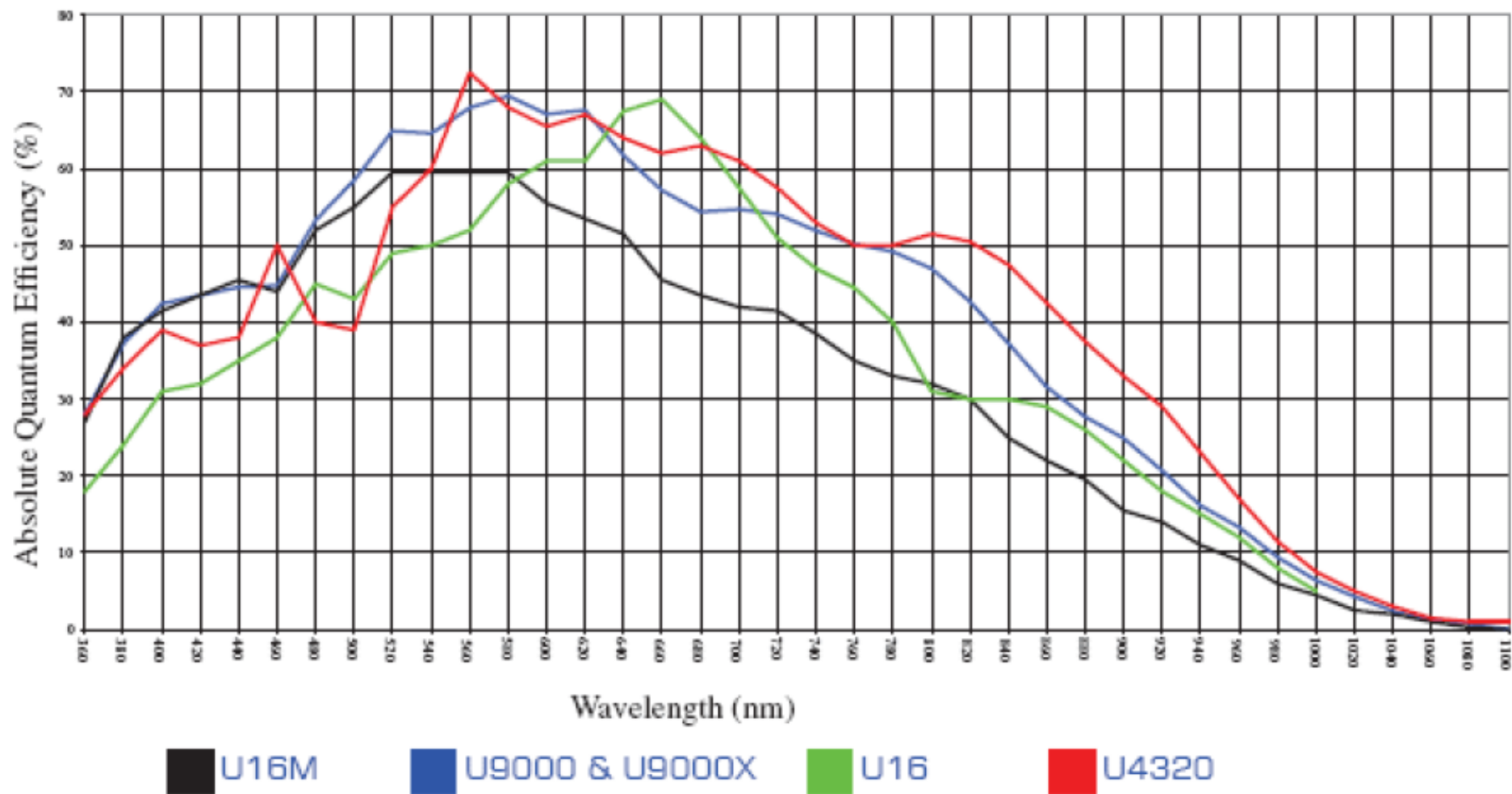




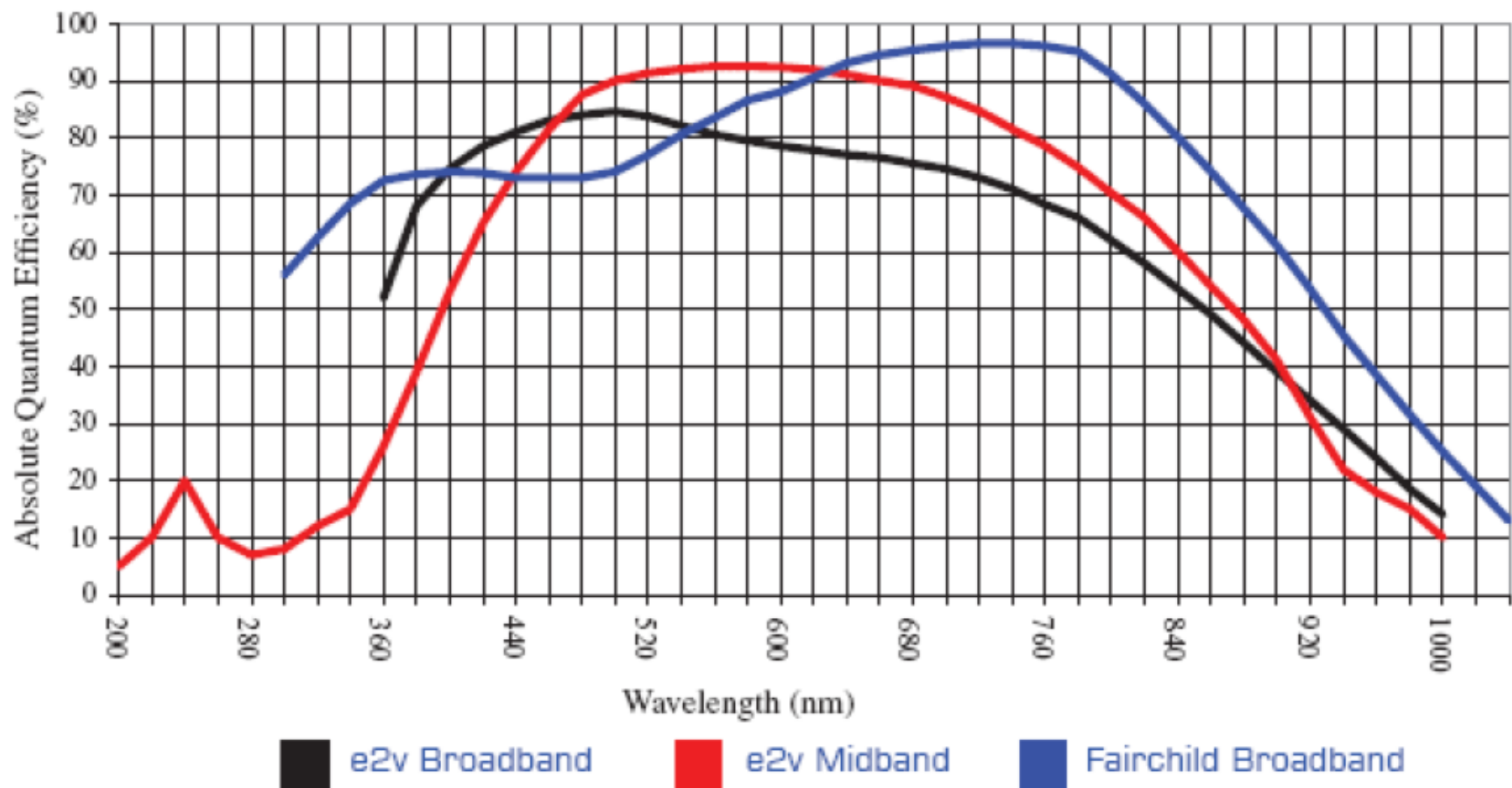
Interline transfer



Front illuminated

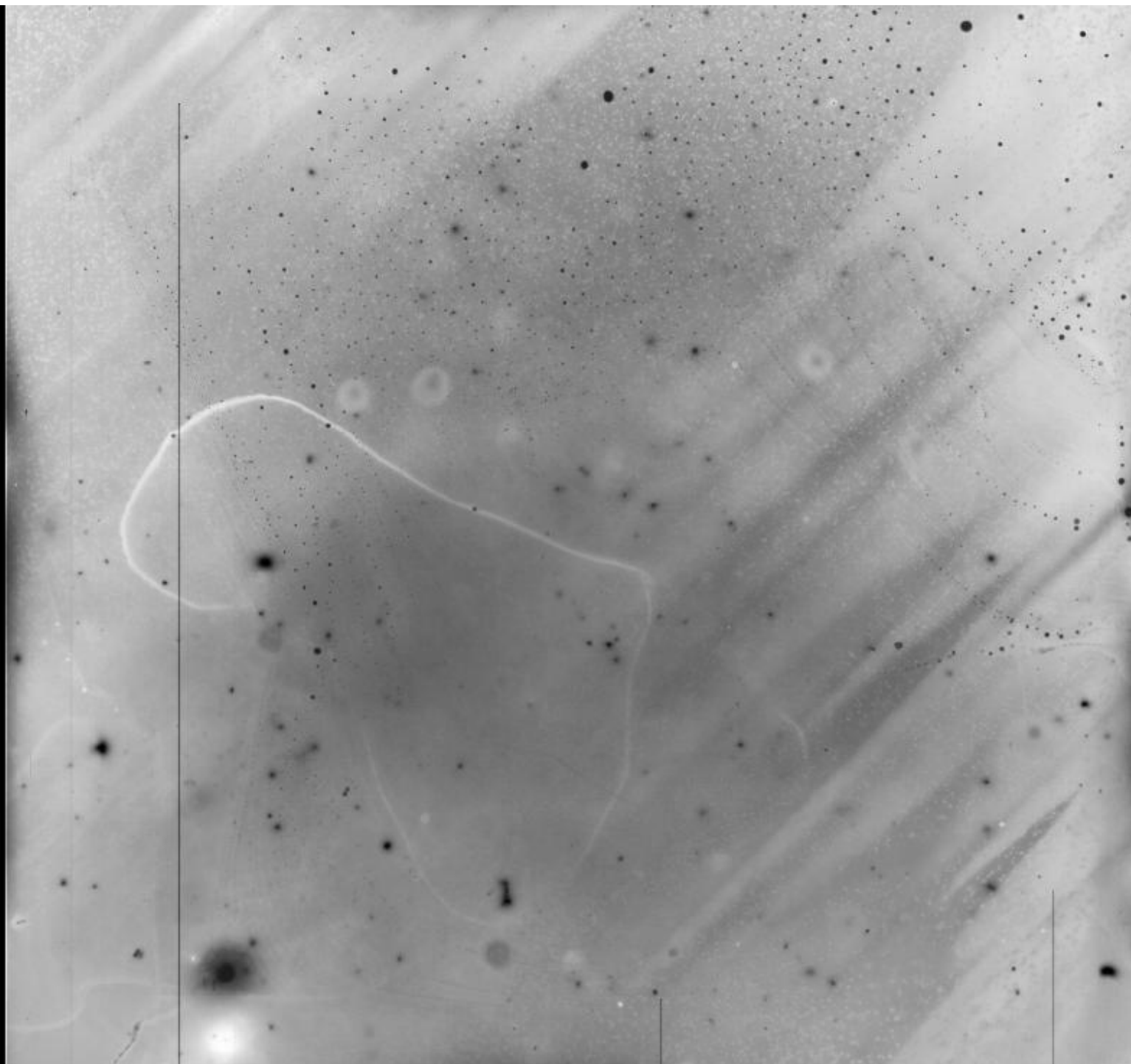


Front illuminated microlens

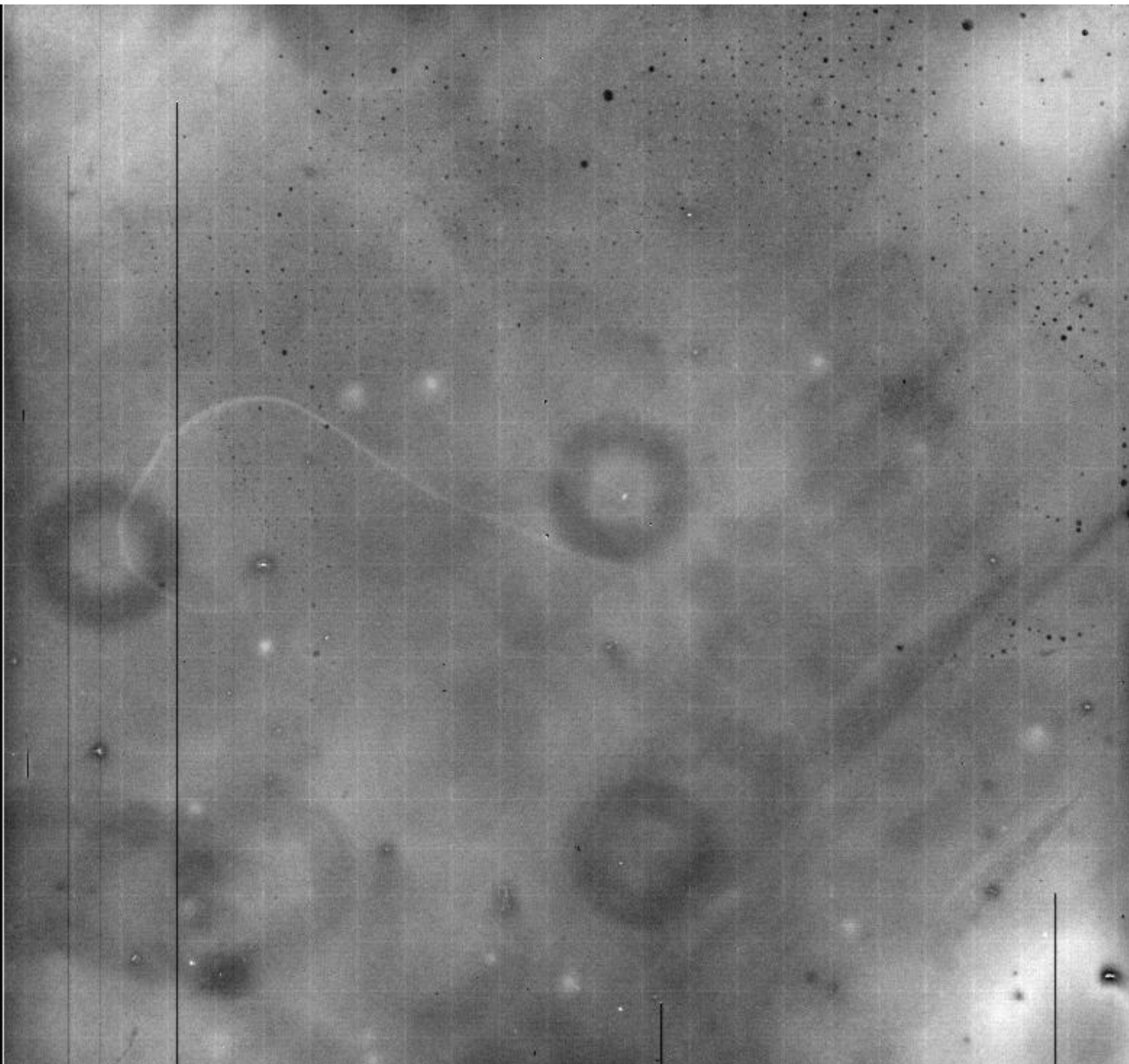


Different AR coatings for back-illuminated

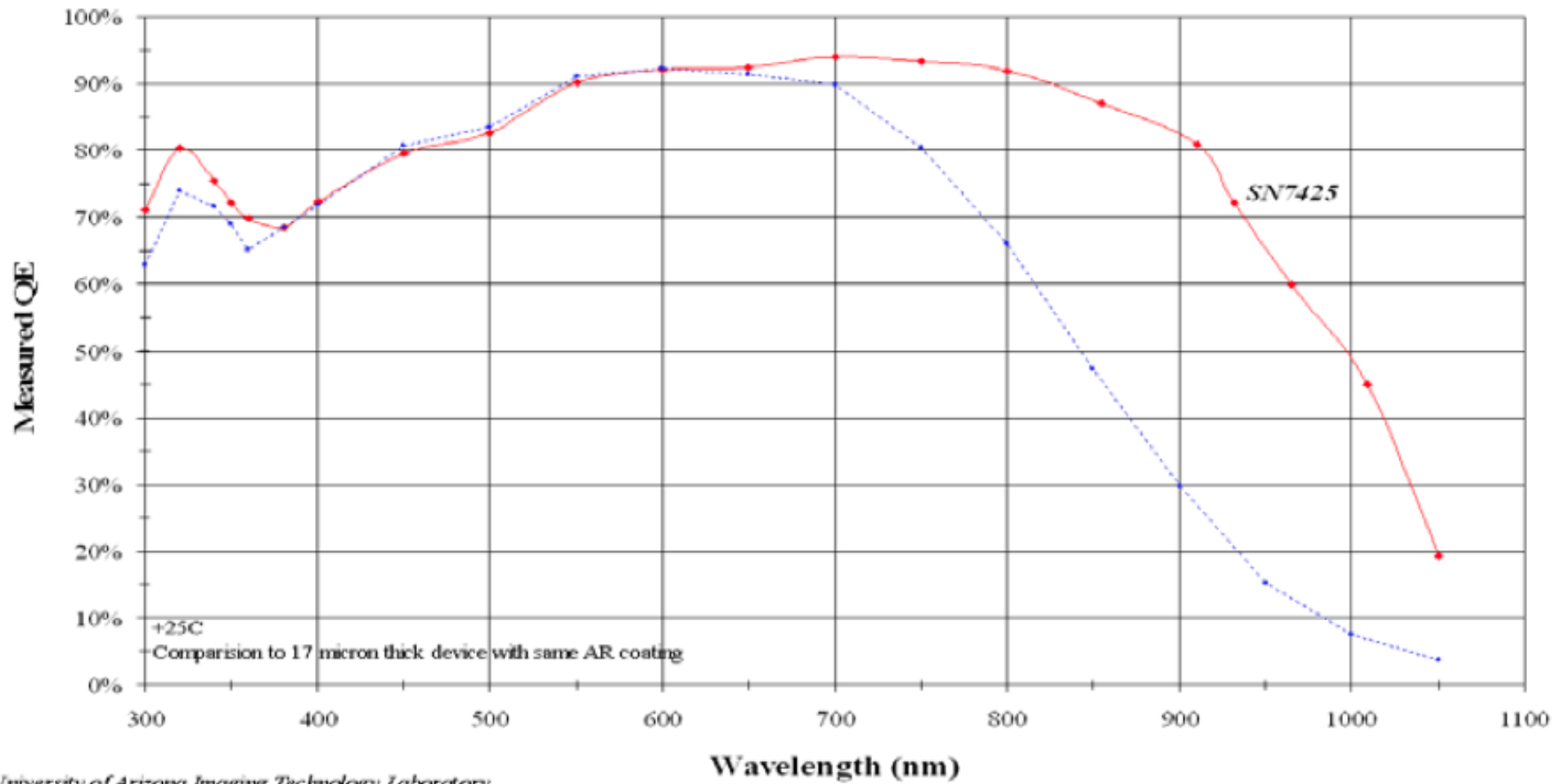
Blue flat; Ti800



Red flat, T1800

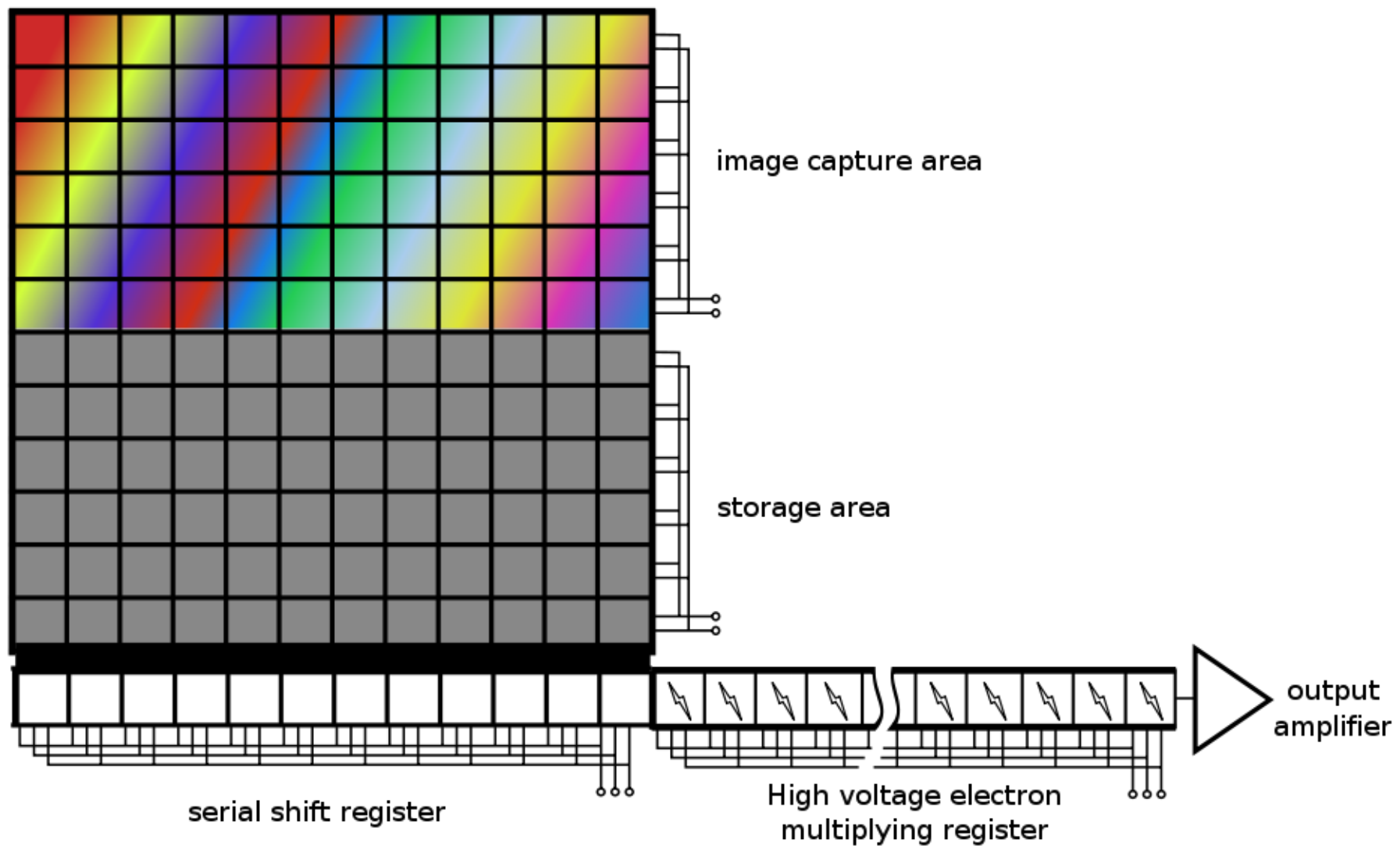


LSST STA1759A
SN7425



University of Arizona Imaging Technology Laboratory

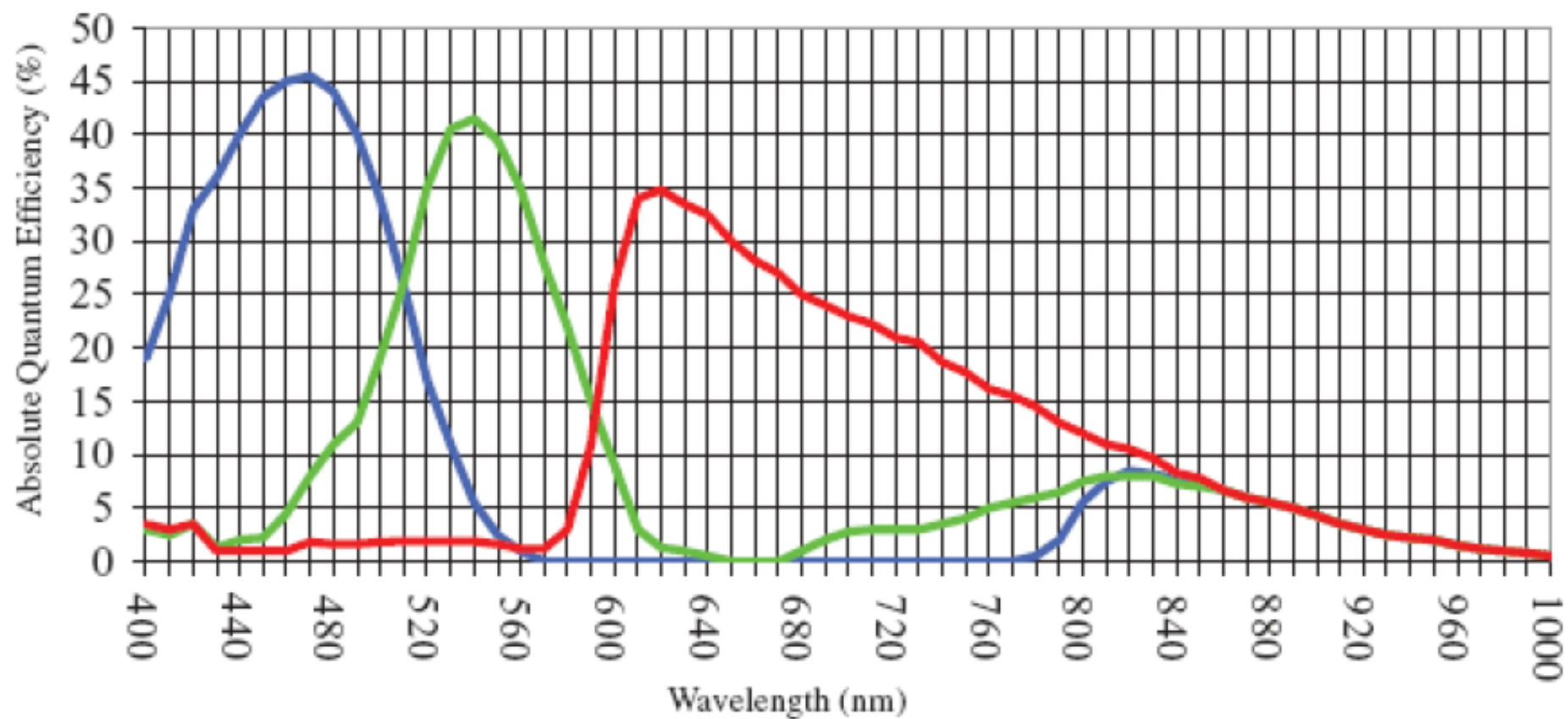
Deep depletion CCD



EMCCD (credit: J. Sanchez)

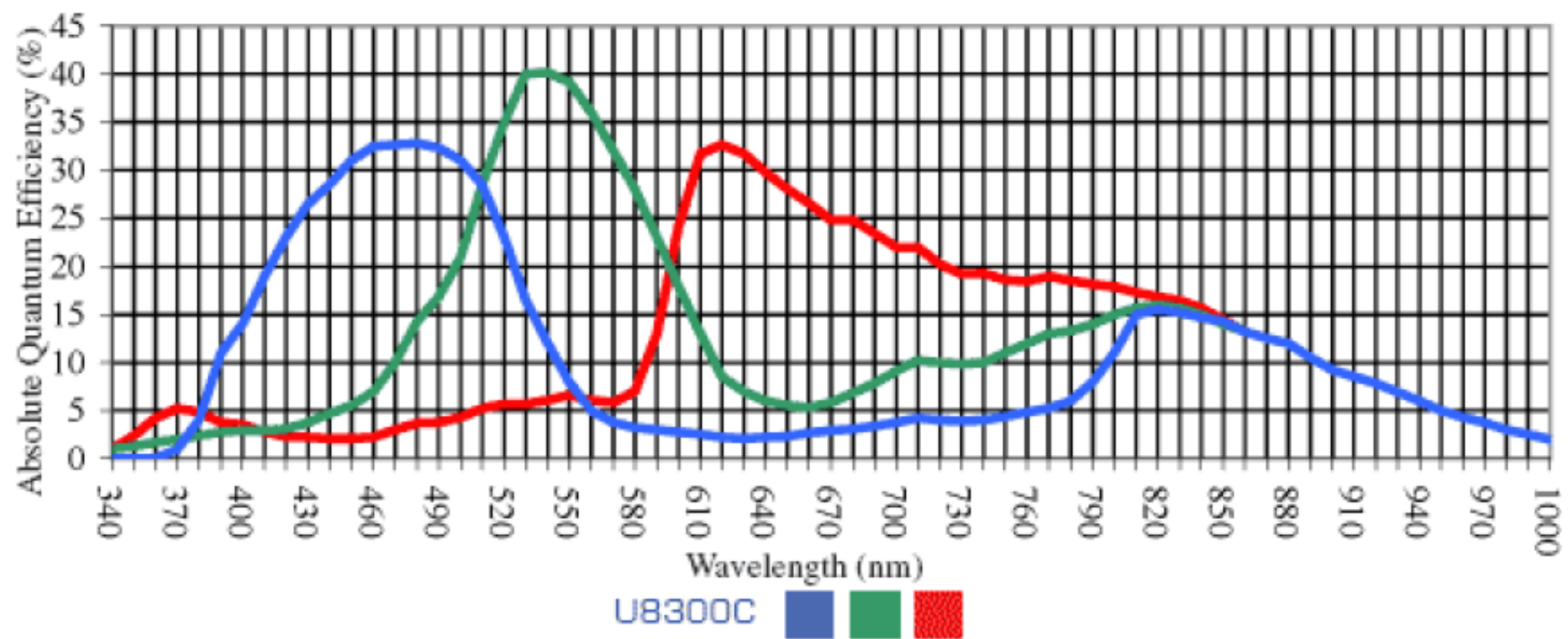
Color CCD

- Monochrome CCD with colored layers added
- One-shot color is like science CCD (cooled, 16-bit ADC, etc.)

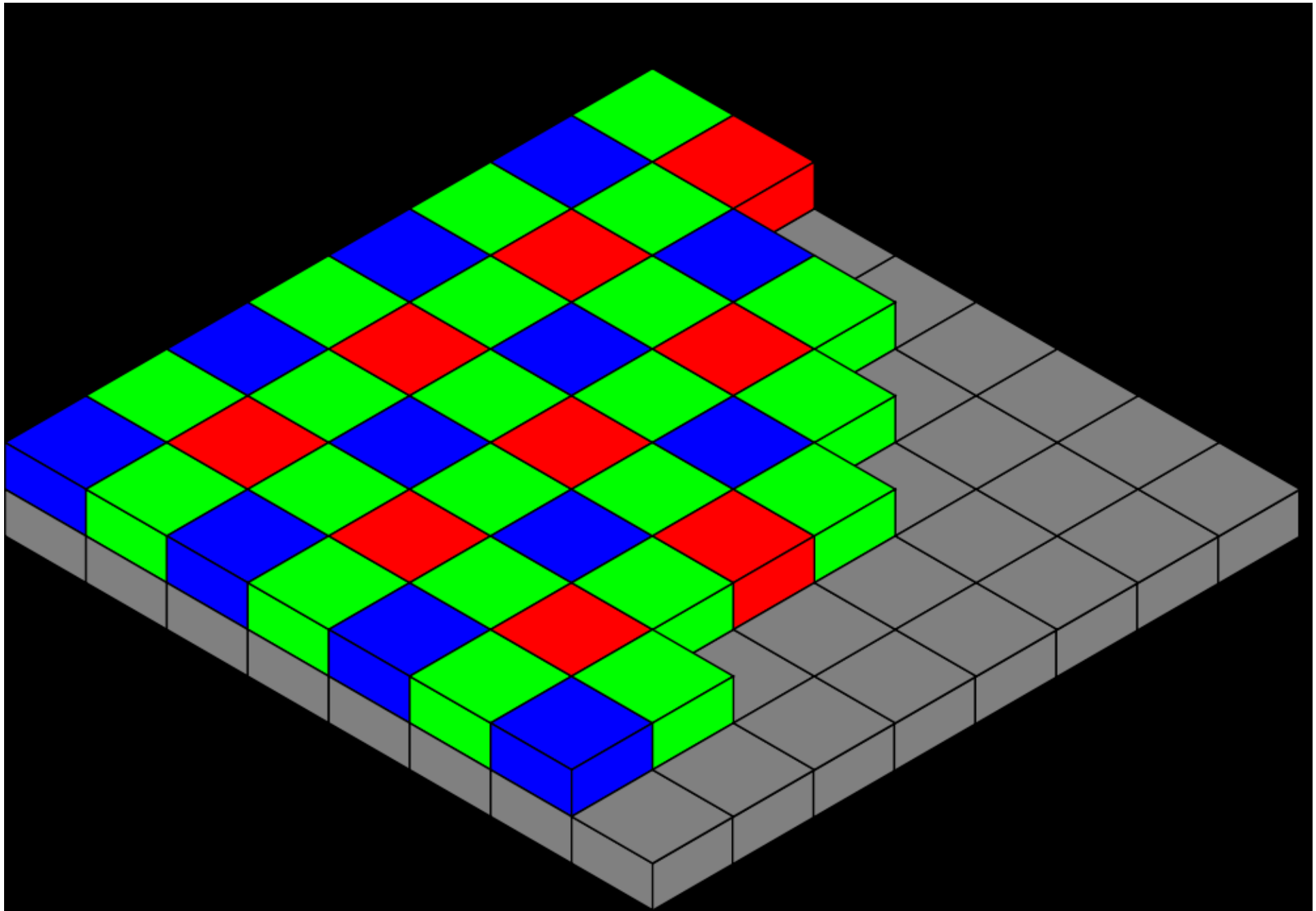


U16000, U4000, & U2000 Color

Color CCDs, note red leak

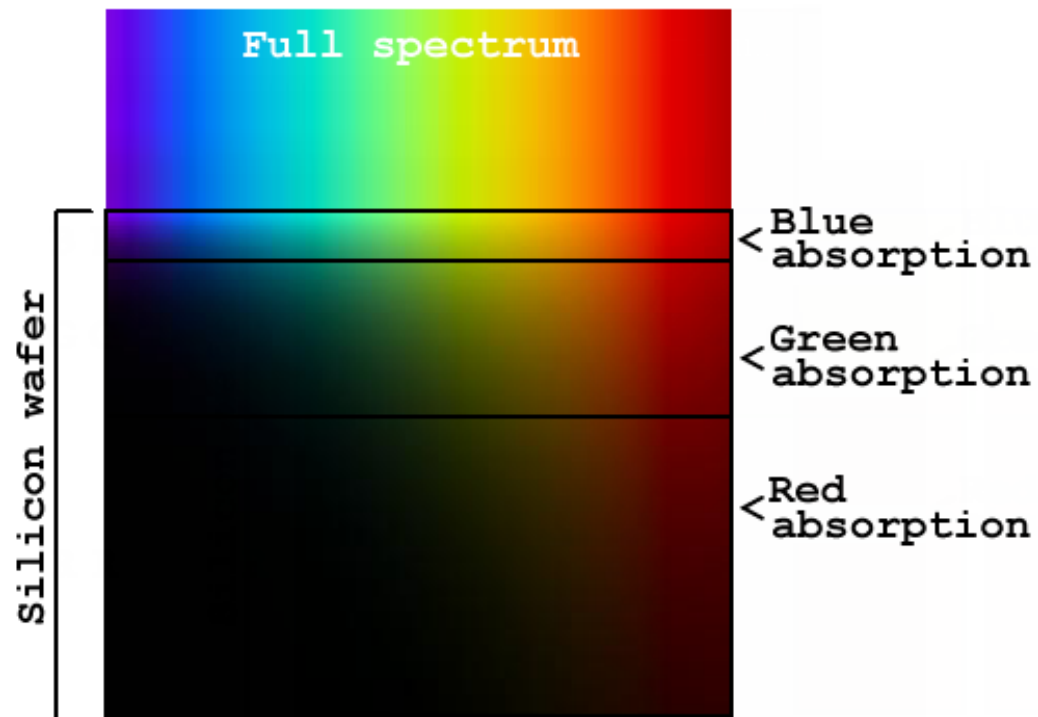


KSF8300C, note red leak

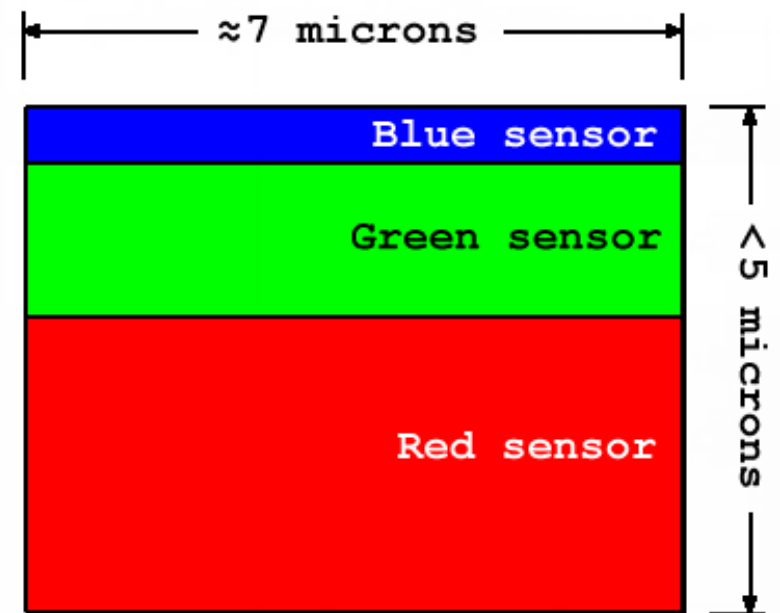


Bayer pattern (credit: C. Burnett)

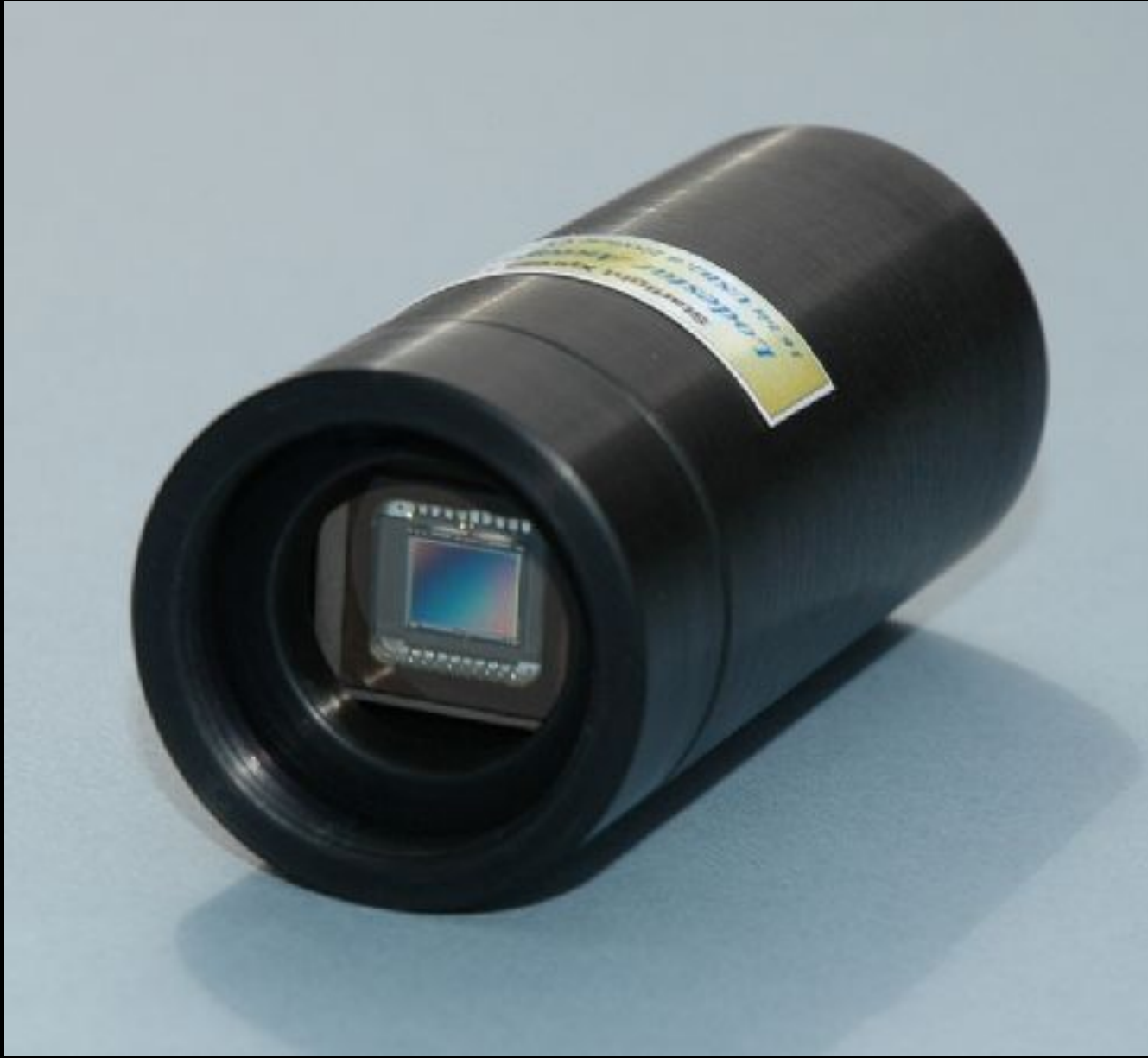
Silicon color absorption



Foveon X3 sensor stack

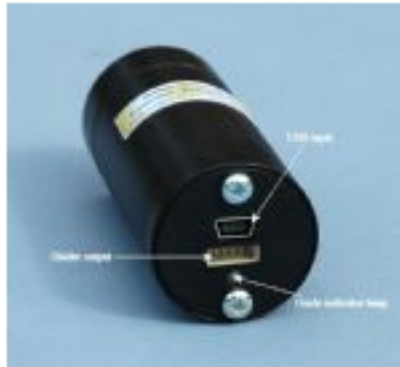


Foveon X3 sensor (Sigma)



Lodestar guider

Starlight Xpress Lodestar Autoguider Specifications...



- CCD type: ICX429AL Sony Exview interline CCD with low dark current and vertical anti-blooming.
- CCD Full resolution Pixel data: Pixel size: 8.2 μ m x 8.4 μ m, Image format: 752 x 580 pixels
- CCD Image area: 6.4mm (Horizontal) x 4.75mm (Vertical).
- CCD quality: Grade 1
- Spectral Response: QE max at 620nm (~65%), 35% at 400nm and 770nm.
- Readout Noise: Less than 15 electrons RMS - typically only 10 electrons.
- Full-well capacity: Greater than 50,000 e⁻ (unbinned)
- Anti-blooming: Overload margin greater than 1000x.
- Dark current: Dark frame saturation time greater than 1 hour. Less than 0.1 electrons/second @ + 10C ambient.
- Data format: 16 bits.
- System gain: 0.9 electrons per ADU
- Computer Interface: Built-in USB 2.0 compatible interface.
- Image download time: Typically 0.2 seconds at full resolution using USB 2.0.
- Power requirements: USB powered.
- Cooling system: Ambient air cooling.
- Size: 32 x 72mm black anodised aluminium barrel with 25 x 0.75mm 'C mount' thread at the CCD window end & input/output plugs at rear.
- Weight: approx. 50g

Super Low Light B/W Video Security Camera

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- 0.001 lux low light rating
- Compact form factor accepts any CS-mount lens

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Right



Back

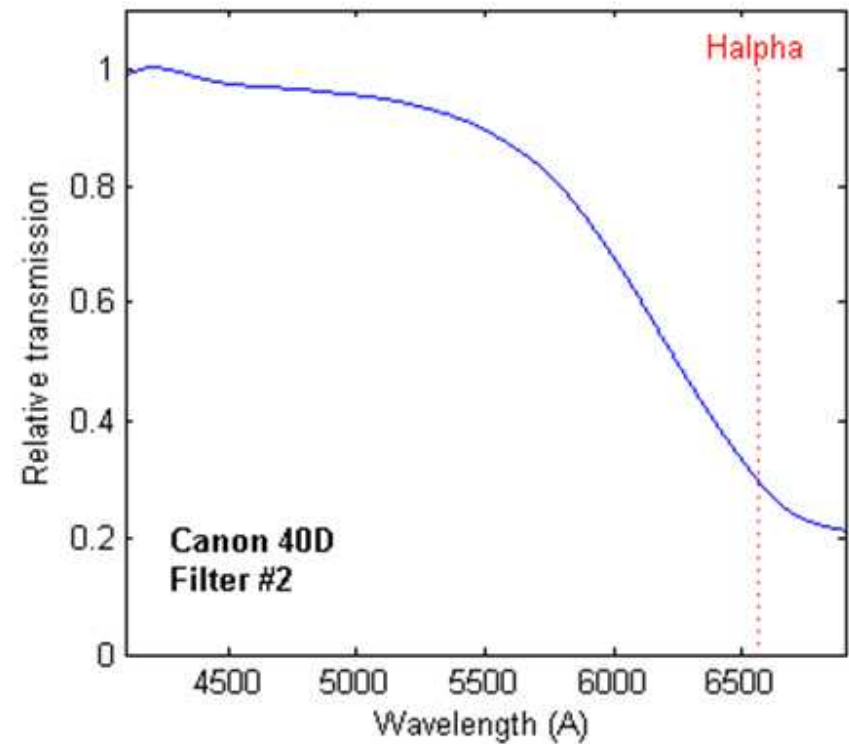
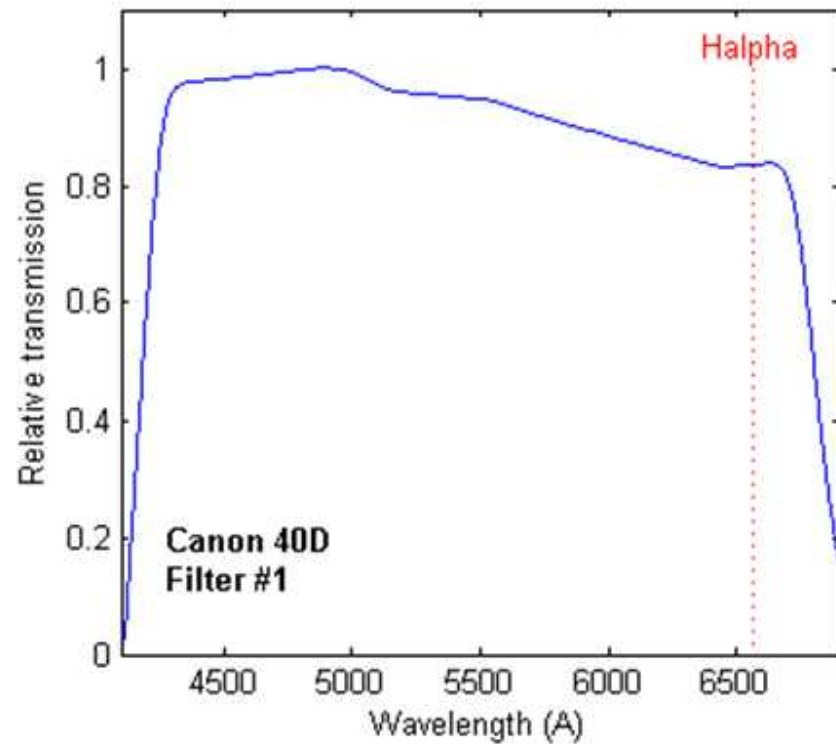


Low Light Video

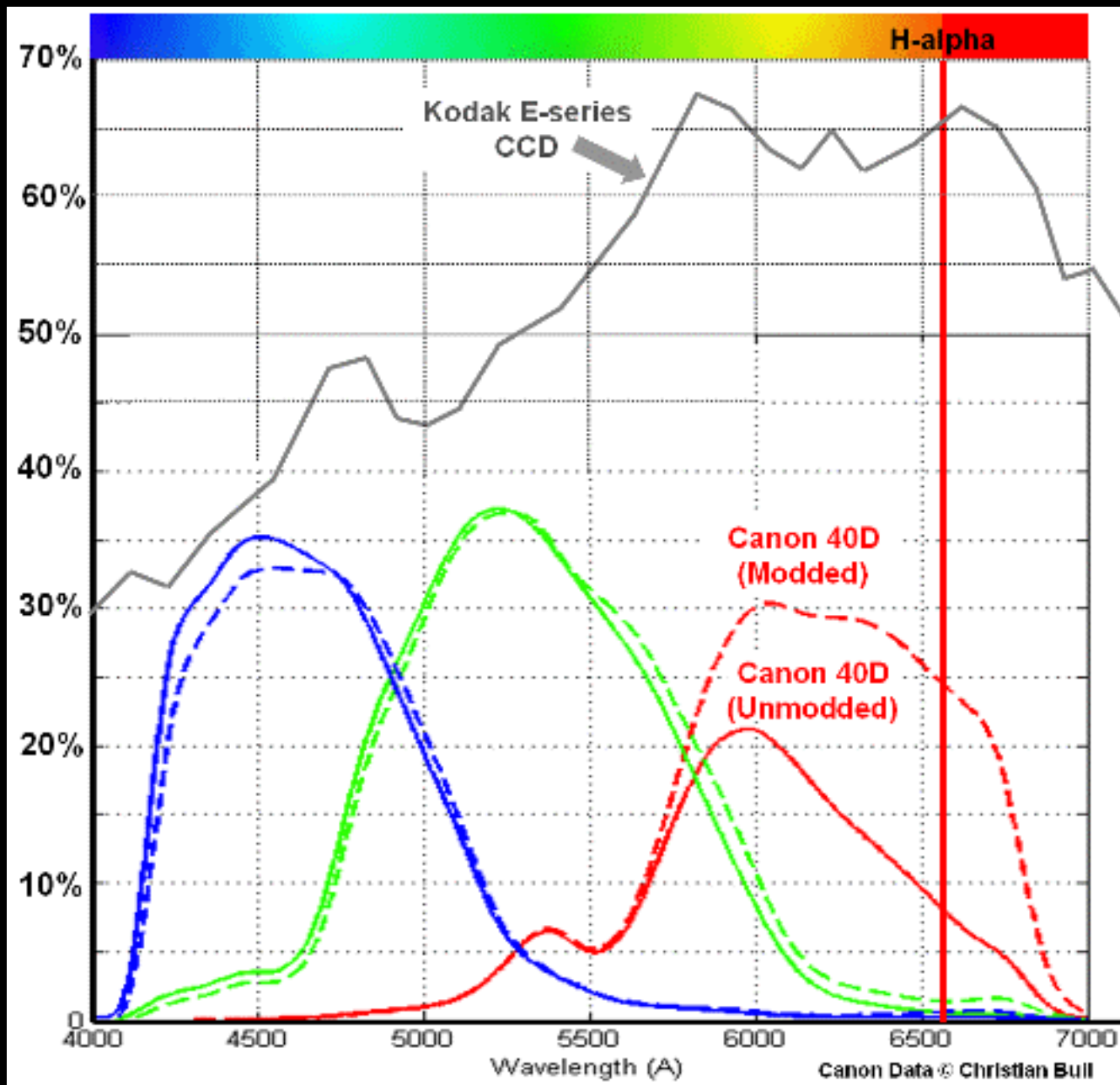
PC-164 webcam/videocam

Typical DSLR Camera





Cover glass comparisons



Canon RGB response

LSST Detectors

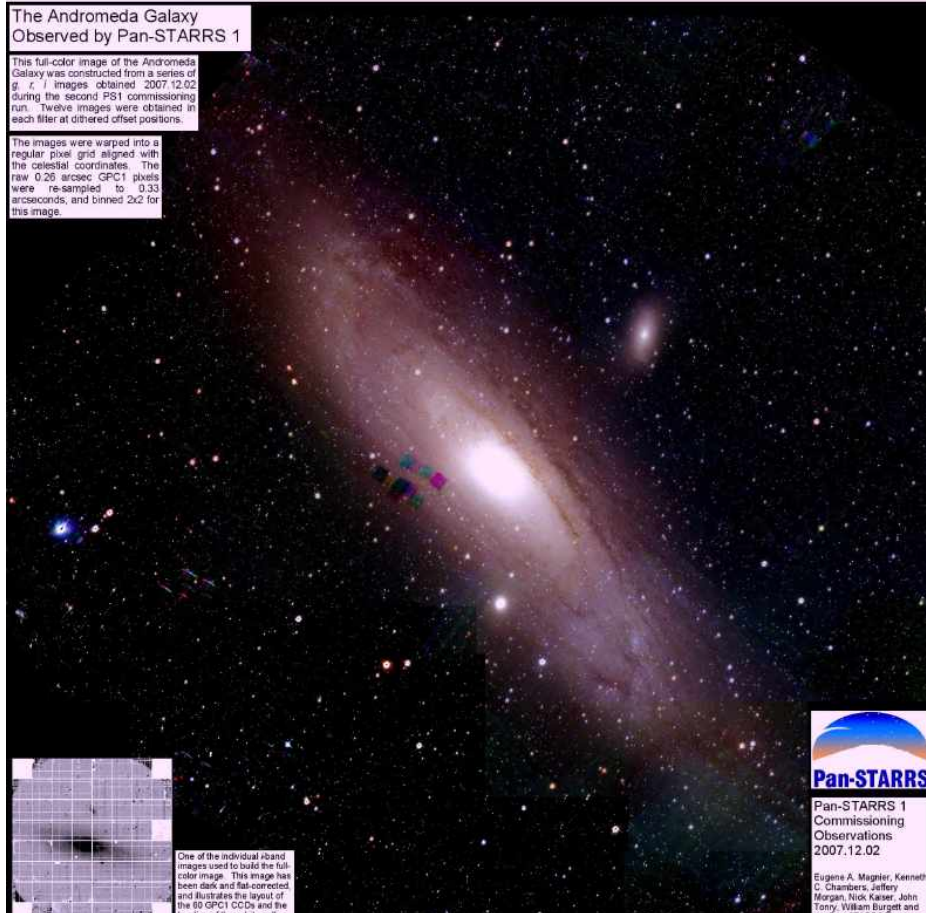


Hubble's Variable in M31

The Andromeda Galaxy Observed by Pan-STARRS 1

This full-color image of the Andromeda Galaxy was constructed from a series of g, r, i images obtained 2007.12.02 during the second PS1 commissioning run. Twelve images were obtained in each filter at dithered offset positions.

The images were warped into a regular pixel grid aligned with the celestial coordinates. The raw 0.28 arcsec GPC1 pixels were re-sampled to 0.33 arcseconds, and binned 2x2 for this image.



One of the individual band images used to build the full-color image. This image has been dark and flat corrected and illustrates the layout of the 60 GPC1 CCDs and the location of the calibrator cells.



Pan-STARRS 1
Commissioning
Observations
2007.12.02

Eugene A. Magnier, Kenneth
C. Chambers, Jeffery
Morgan, Nick Kaiser, John
Tonry, William Burgett and
the Pan-STARRS Team

Note size of PanSTARRS
Gpix camera

M31_V1

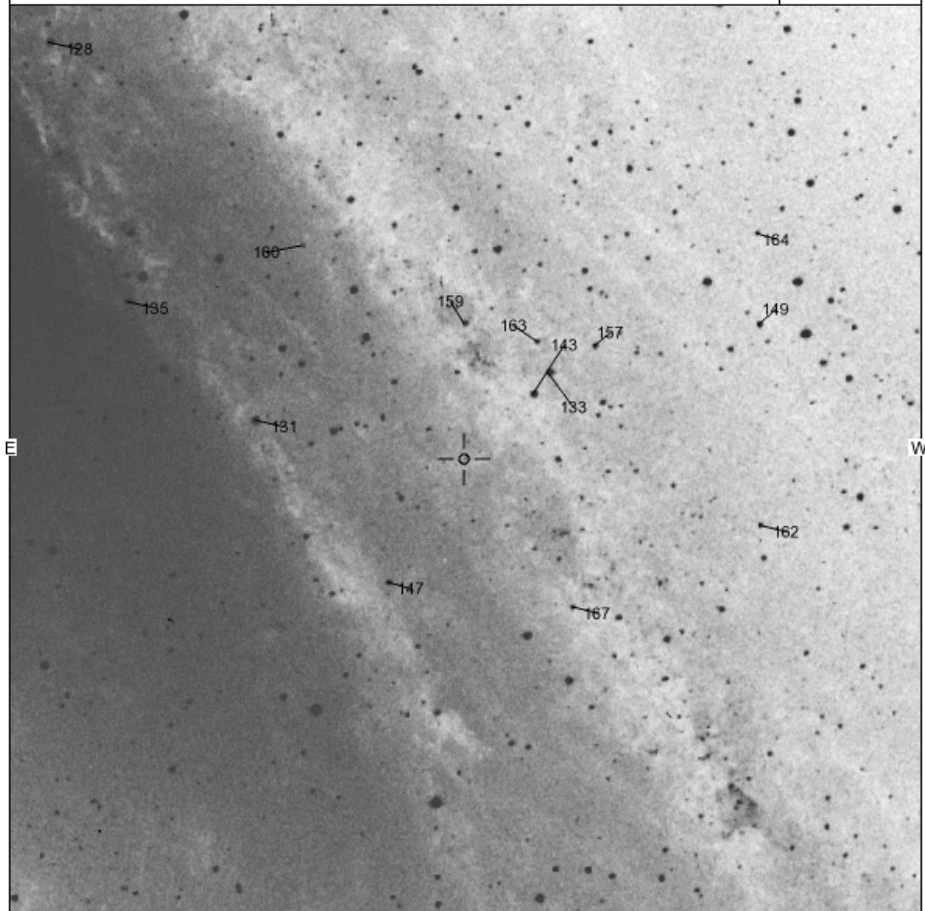
Magn: 19.4 - 0.0
Period: 30.41
Type: DCEP
Spec:

M31_V1

(2000) 00:41:27.30 +41:10:10.4

AAVSO Chart

4909grd



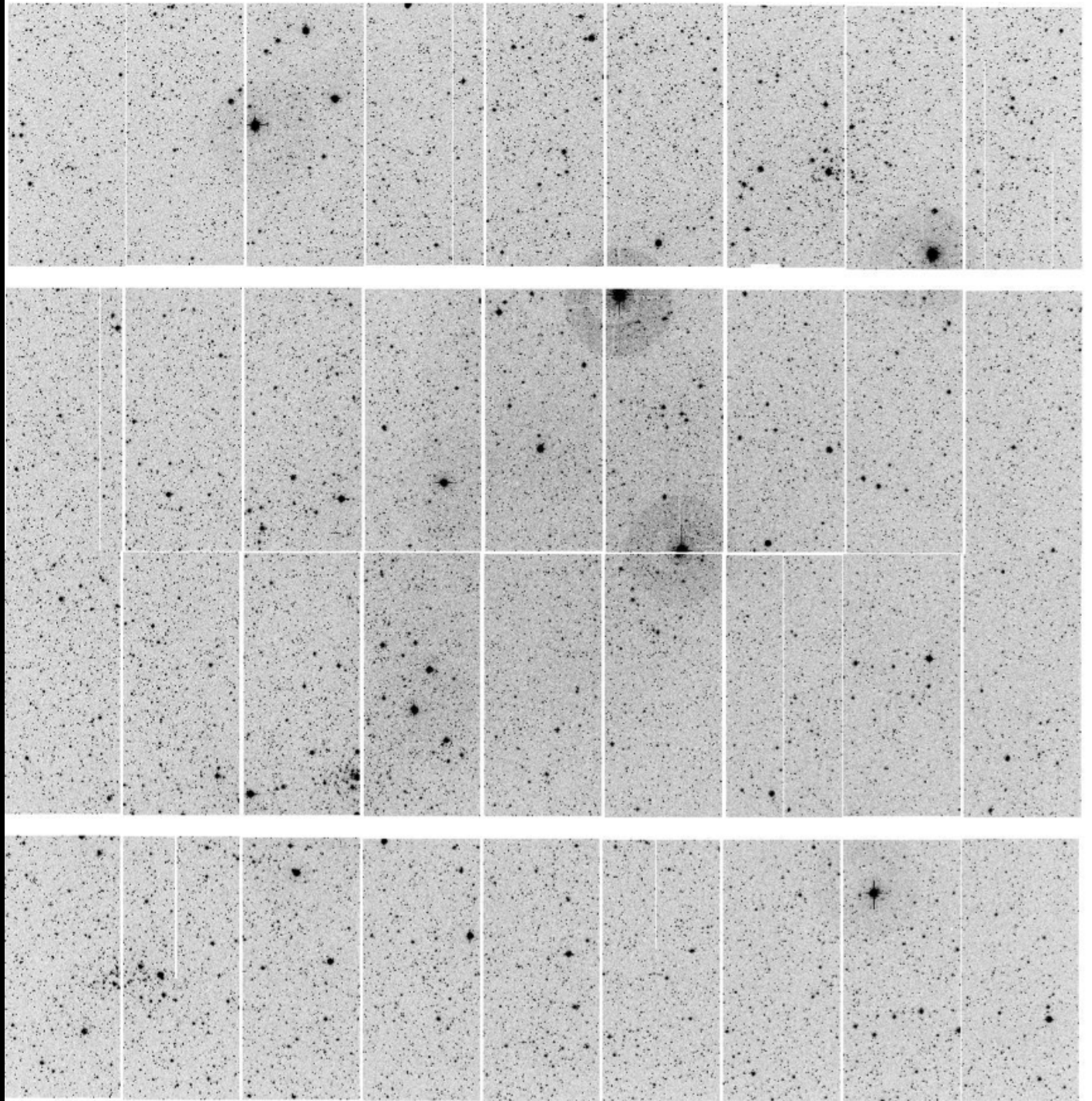
FOV = 18.5'

Please use the photometry table for CCD observations.

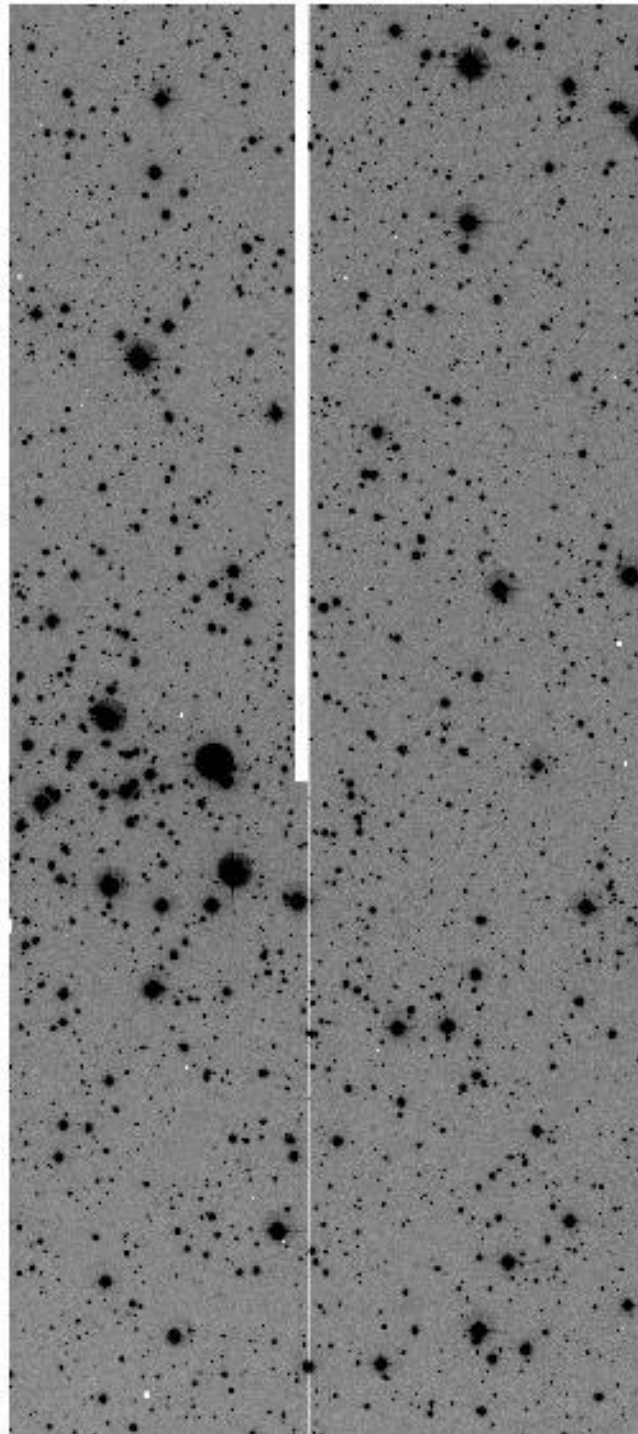
<http://www.aavso.org/vsp/>

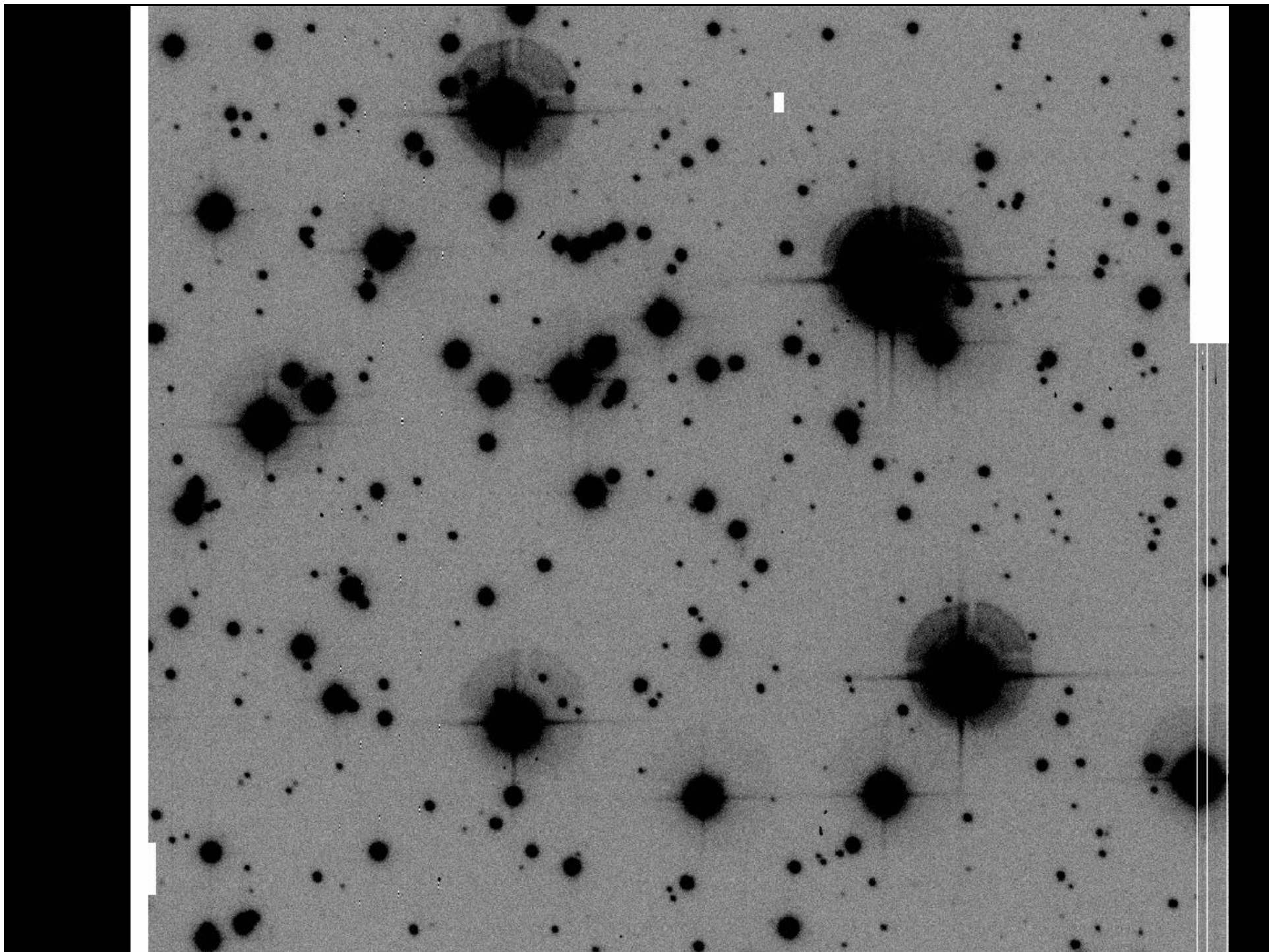
Copyright © 2011 AAVSO

CFHT MegaPrime
36 2kx4k CCDs



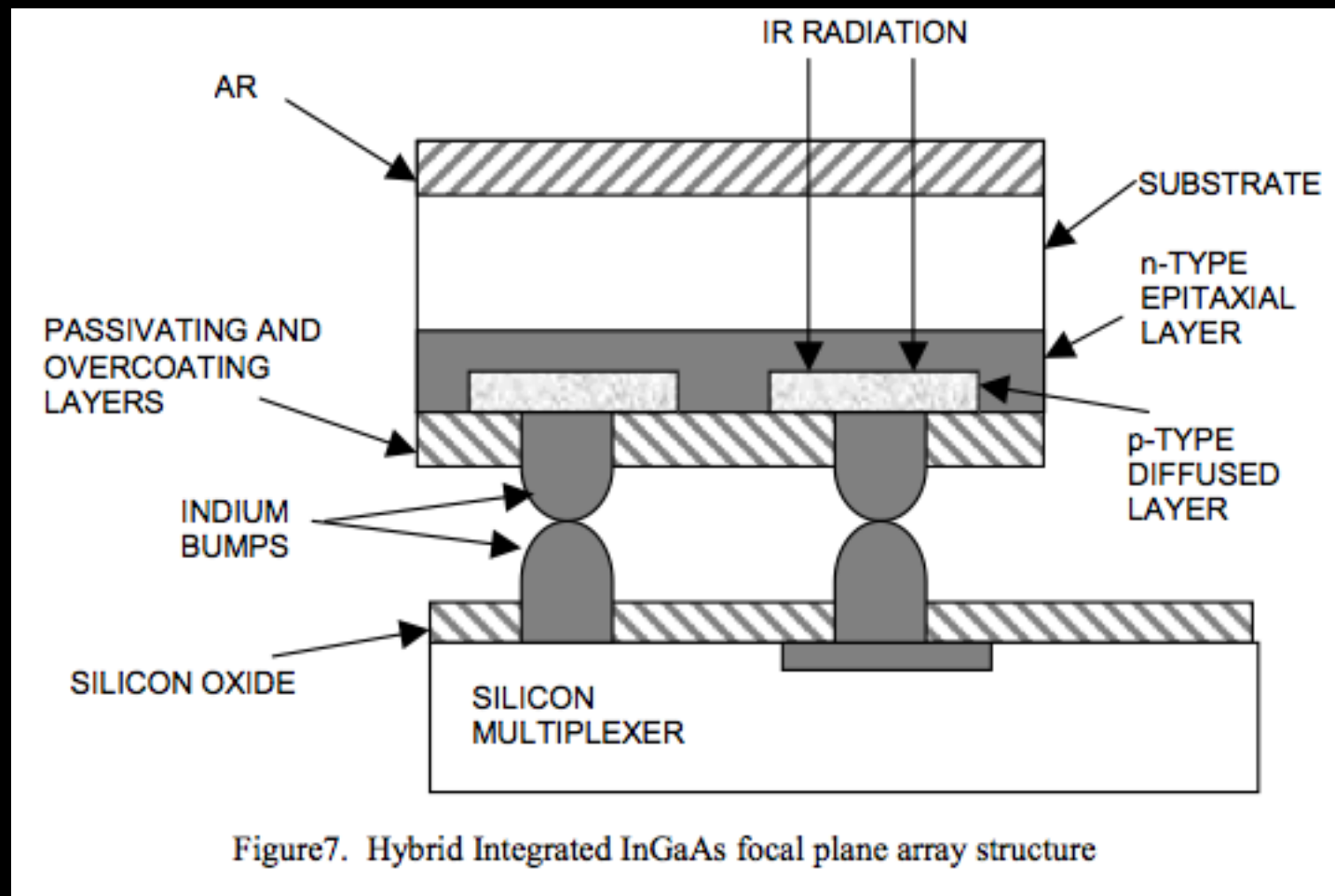
Closeup of one CCD;
note poor quality. Next
slide is portion of this;
note good images



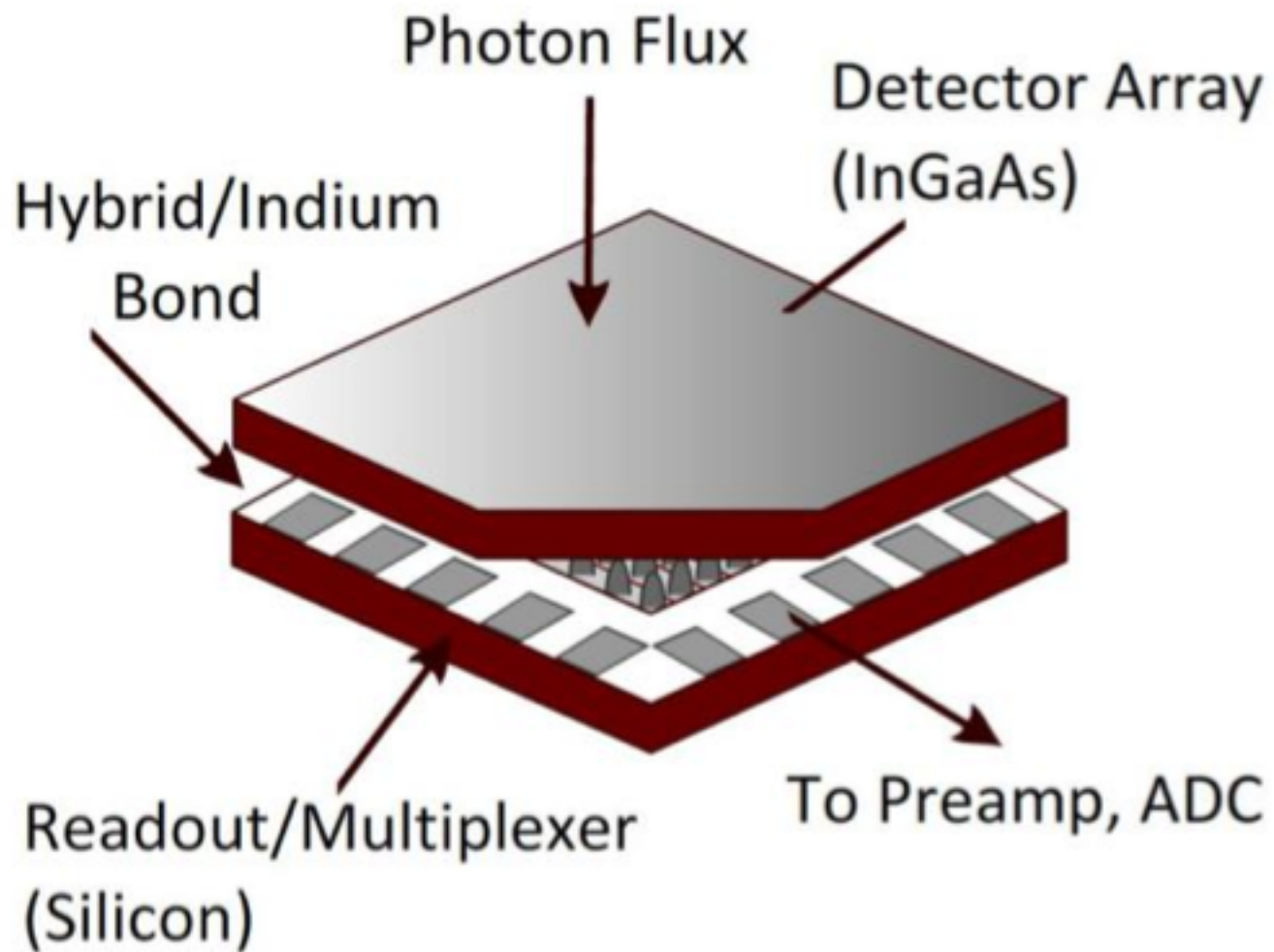


Near Infrared Arrays

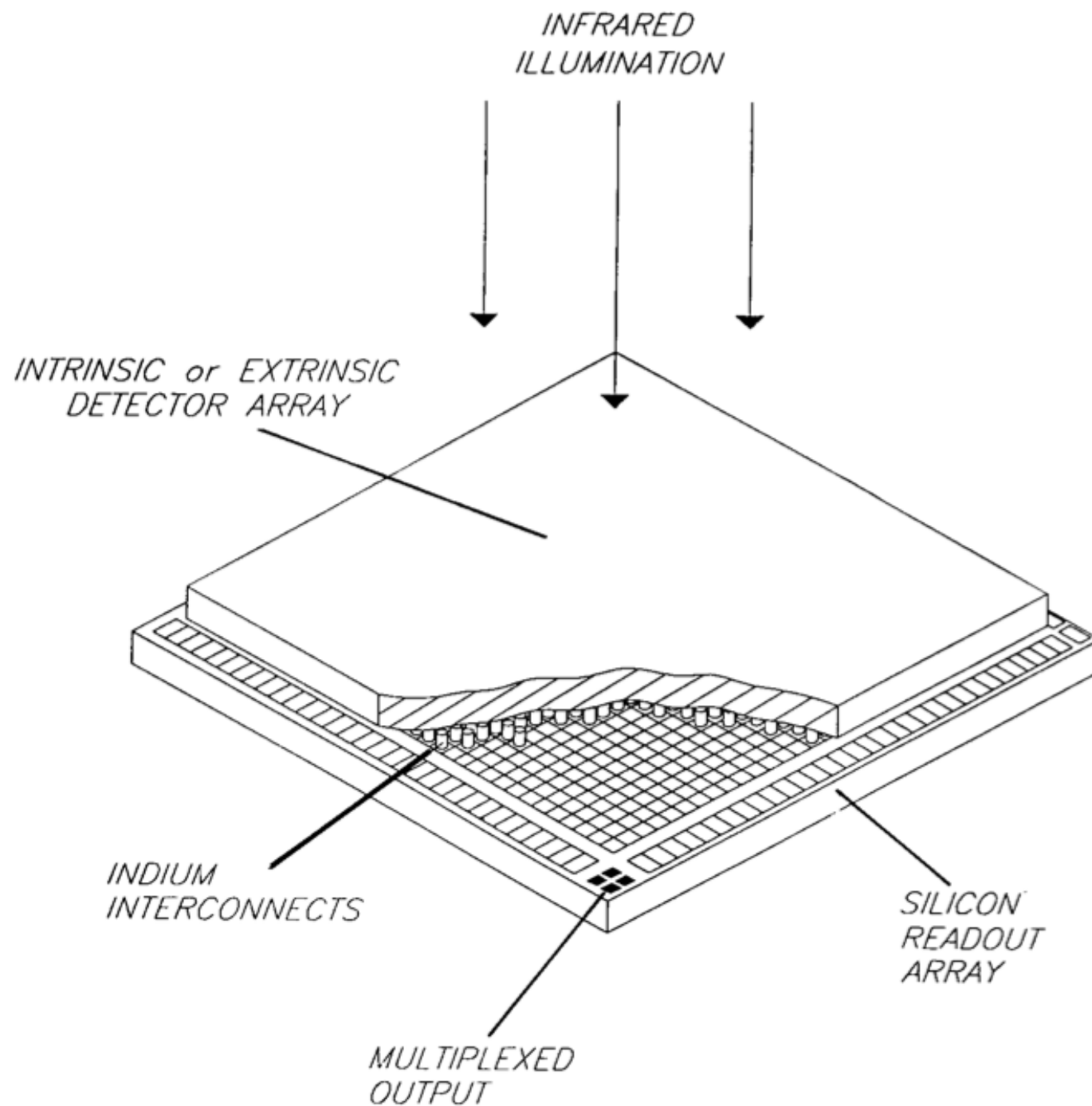
- First InSb 58x62 1990's
- Now 4kx4k
- VERY expensive
- Consumer-level 640x480 available due to telecommunications industry



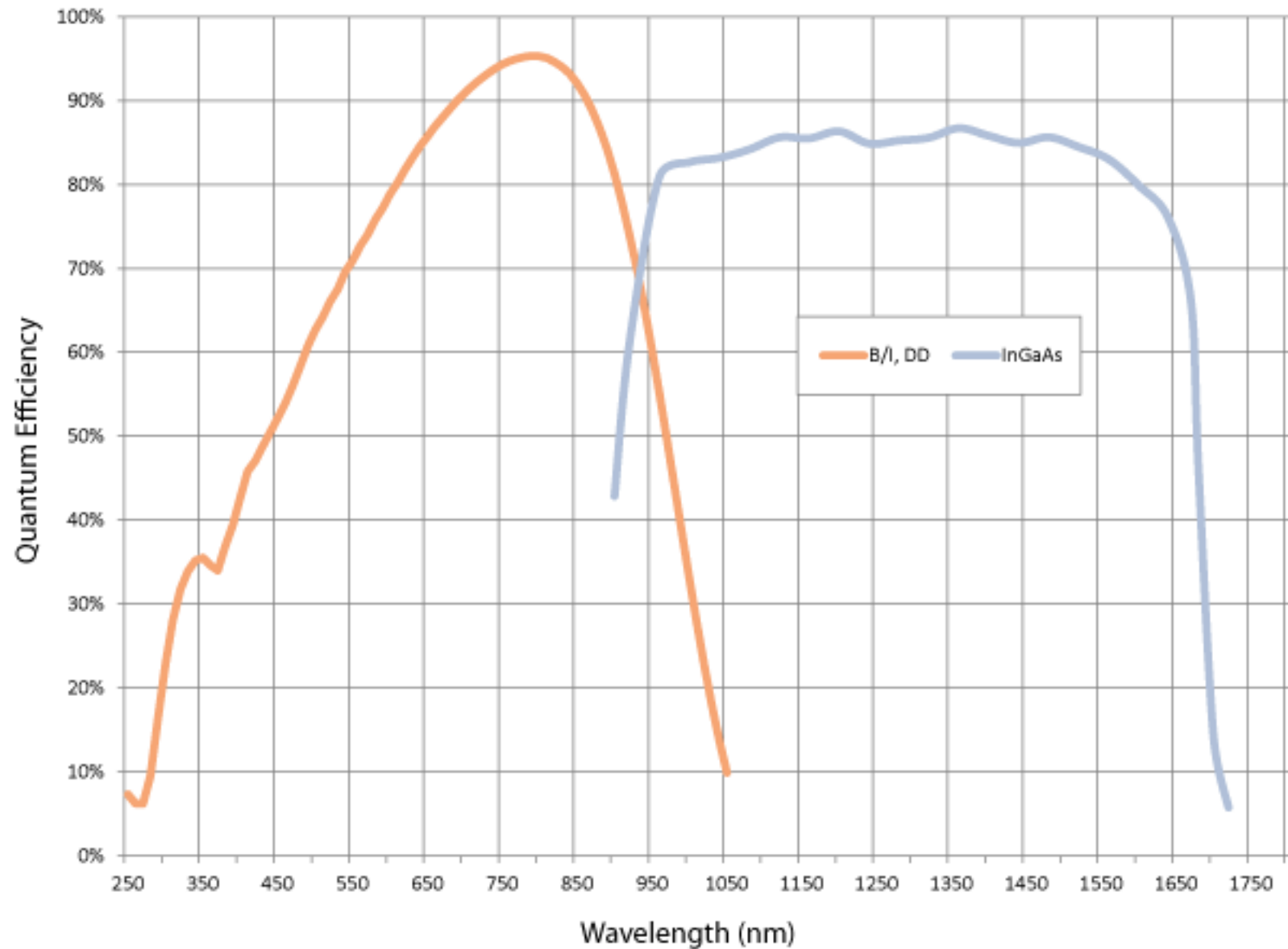
Side view of indium bumps/hybrid



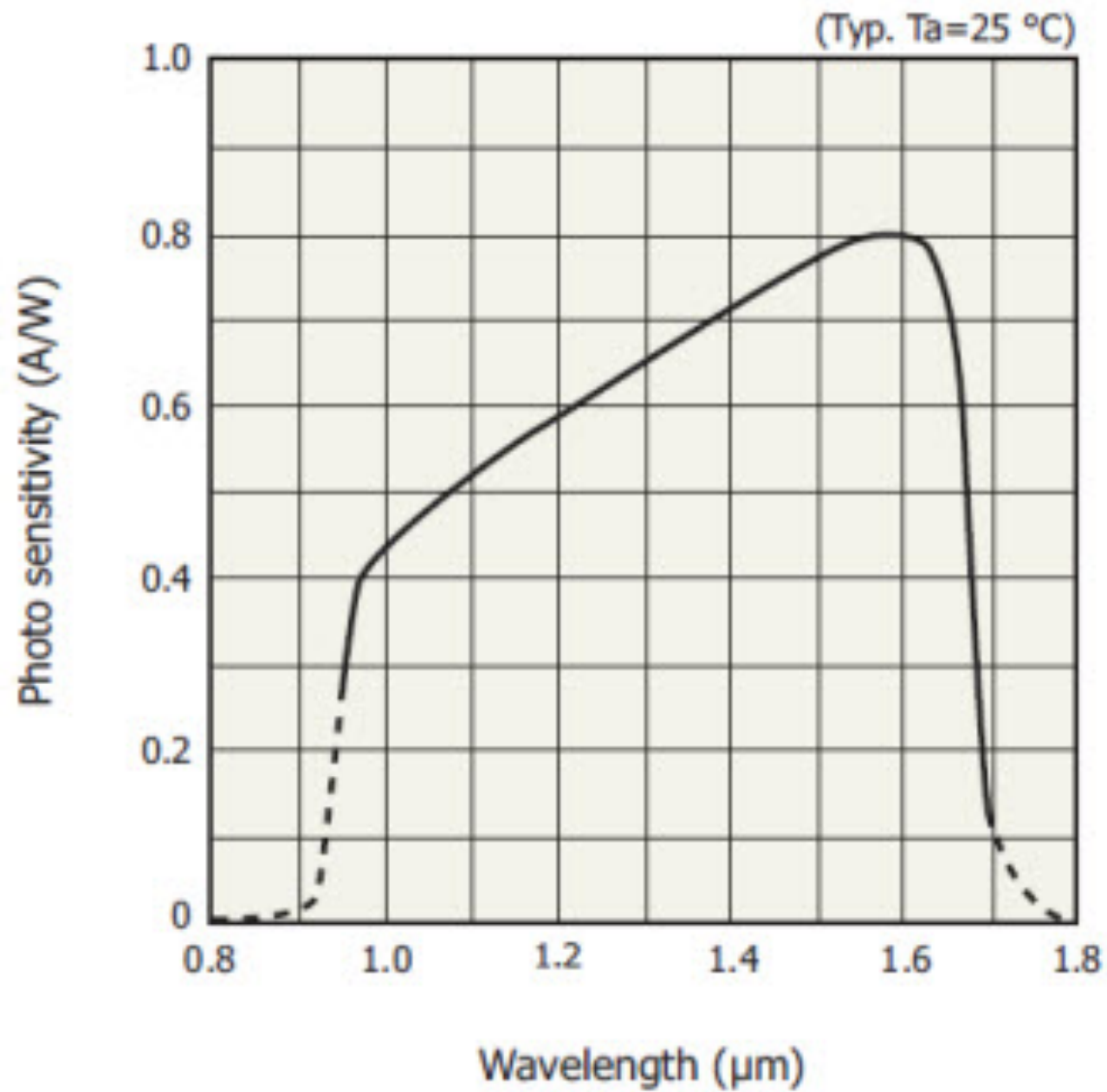
Bump-bonding cartoon



Back Illuminated, Deep Depletion CCD vs. InGaAs FPA QE

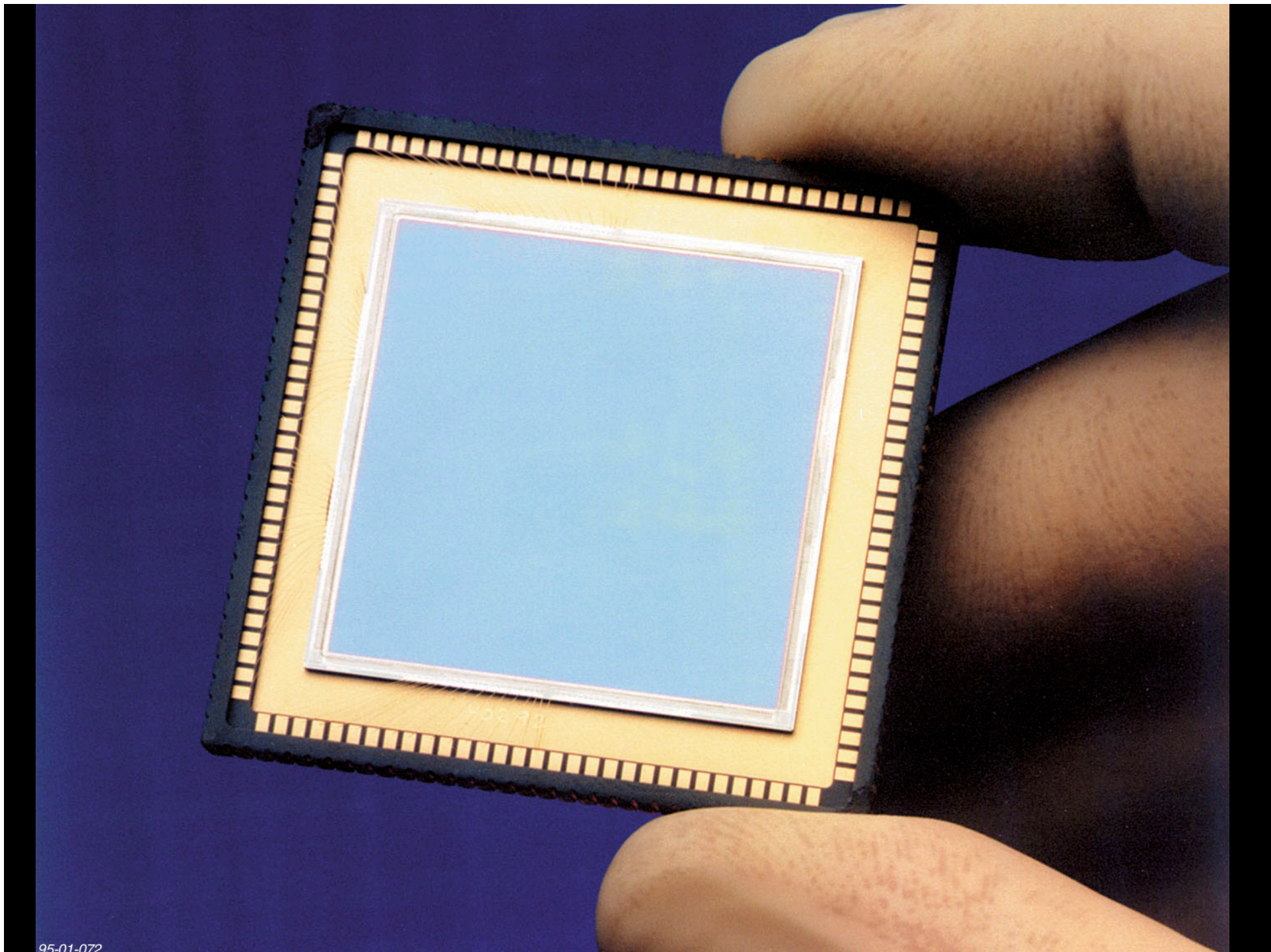


CCD vs. InGaAs

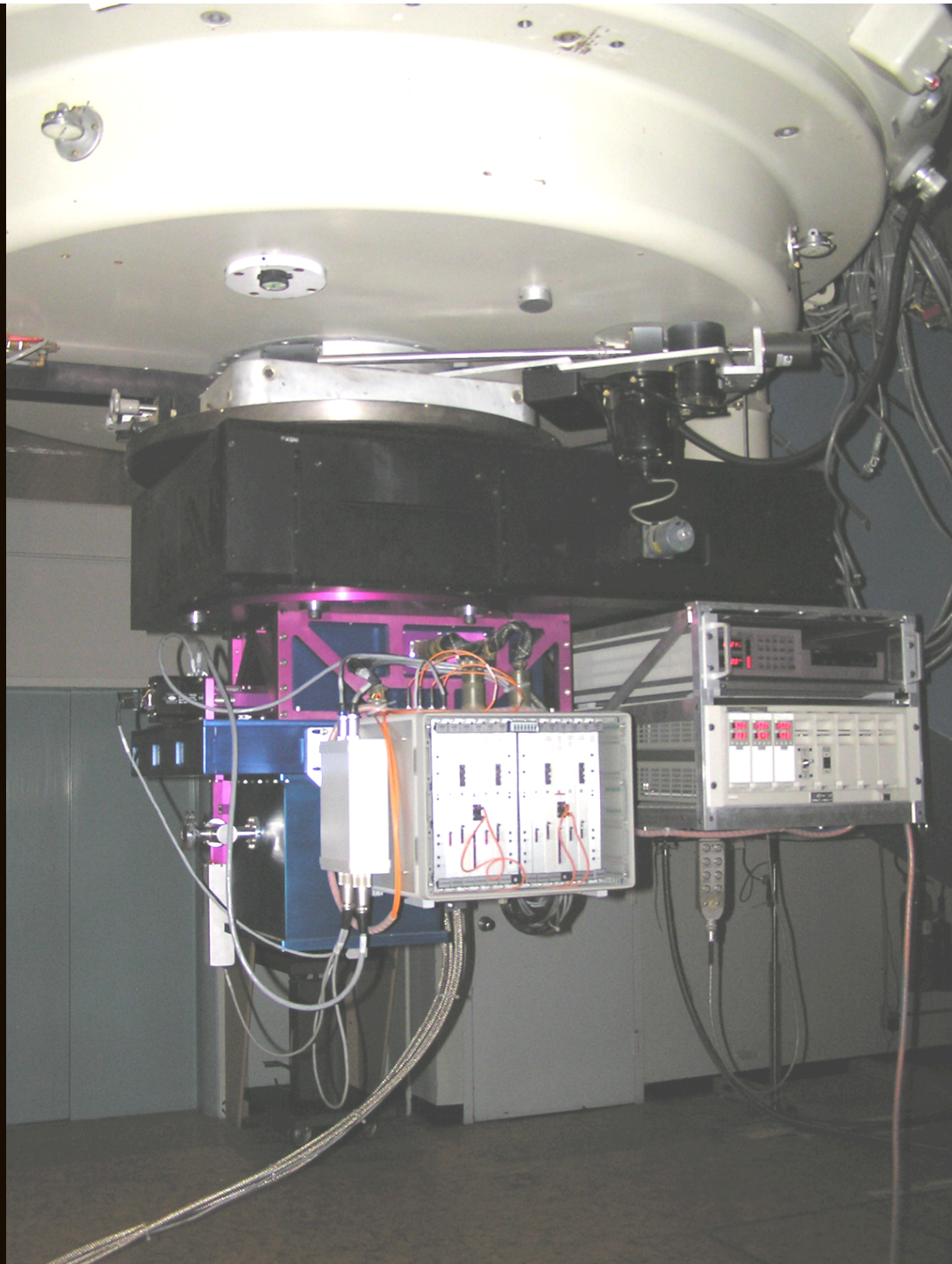


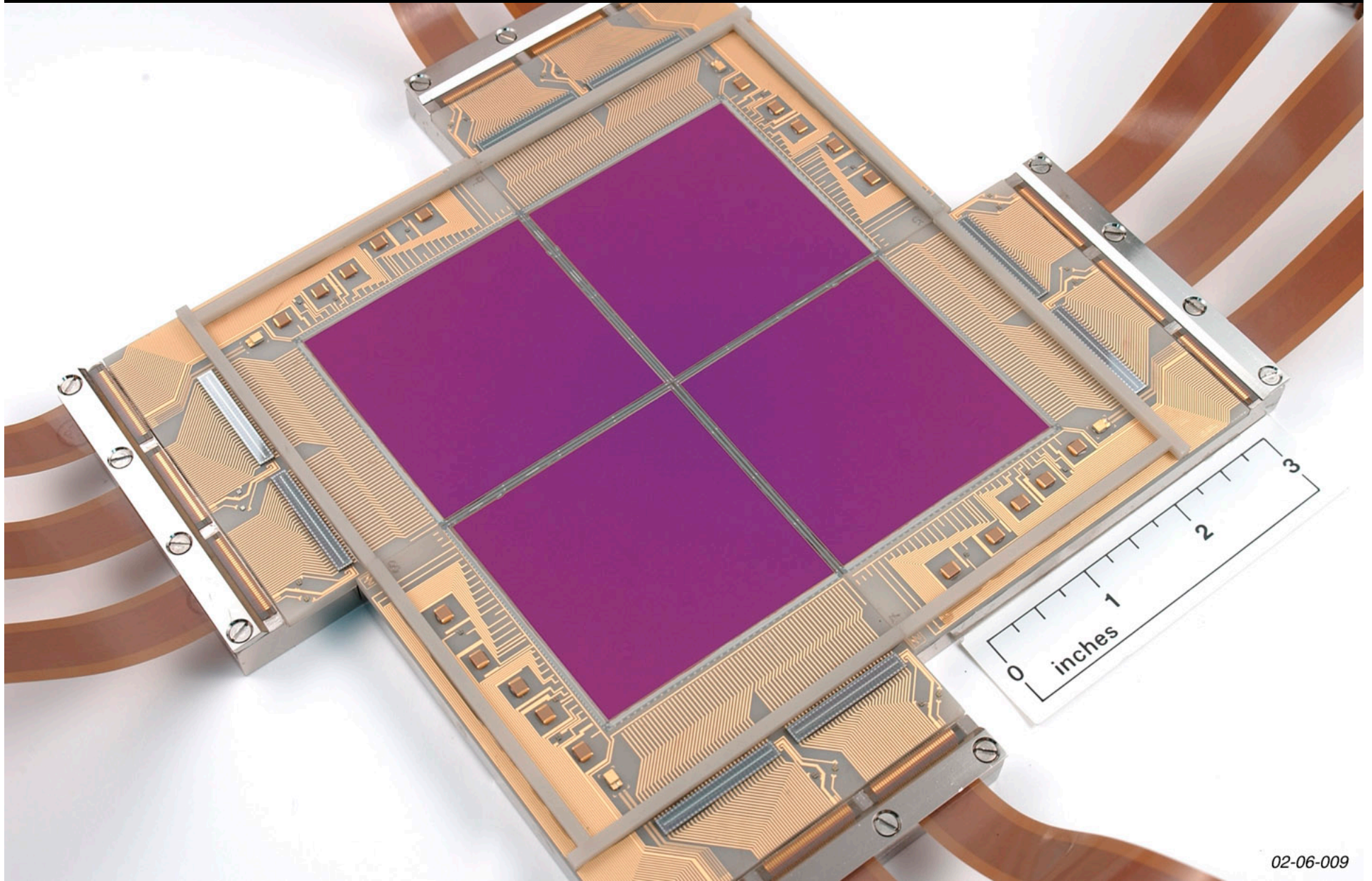
KM1PB0051EB

Typical InGaAs photodiode response









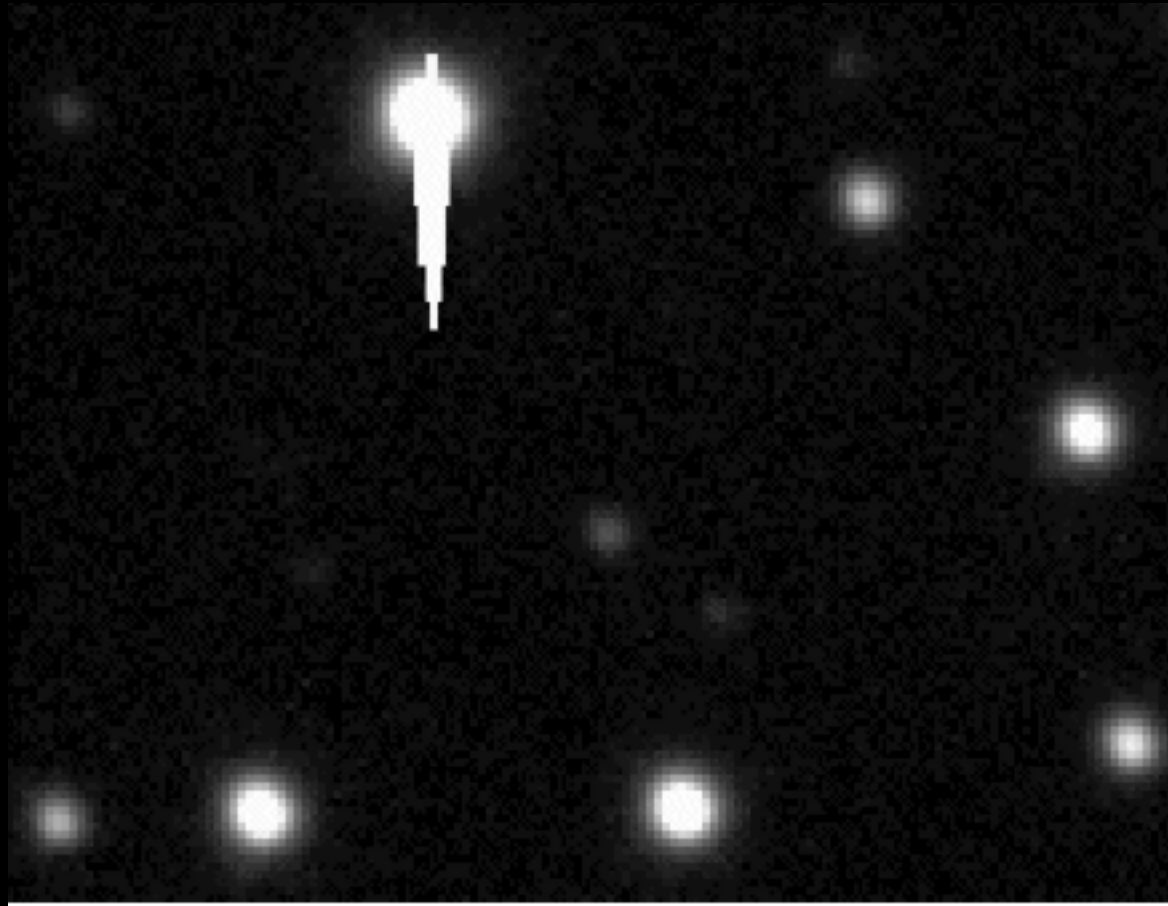
02-06-009

2m0415 brown
dwarf



Observing defects

- Blooming
- Fringing
- Cosmic rays
- Saturation (watch binning)
- Airplanes/satellites



Typical blooming

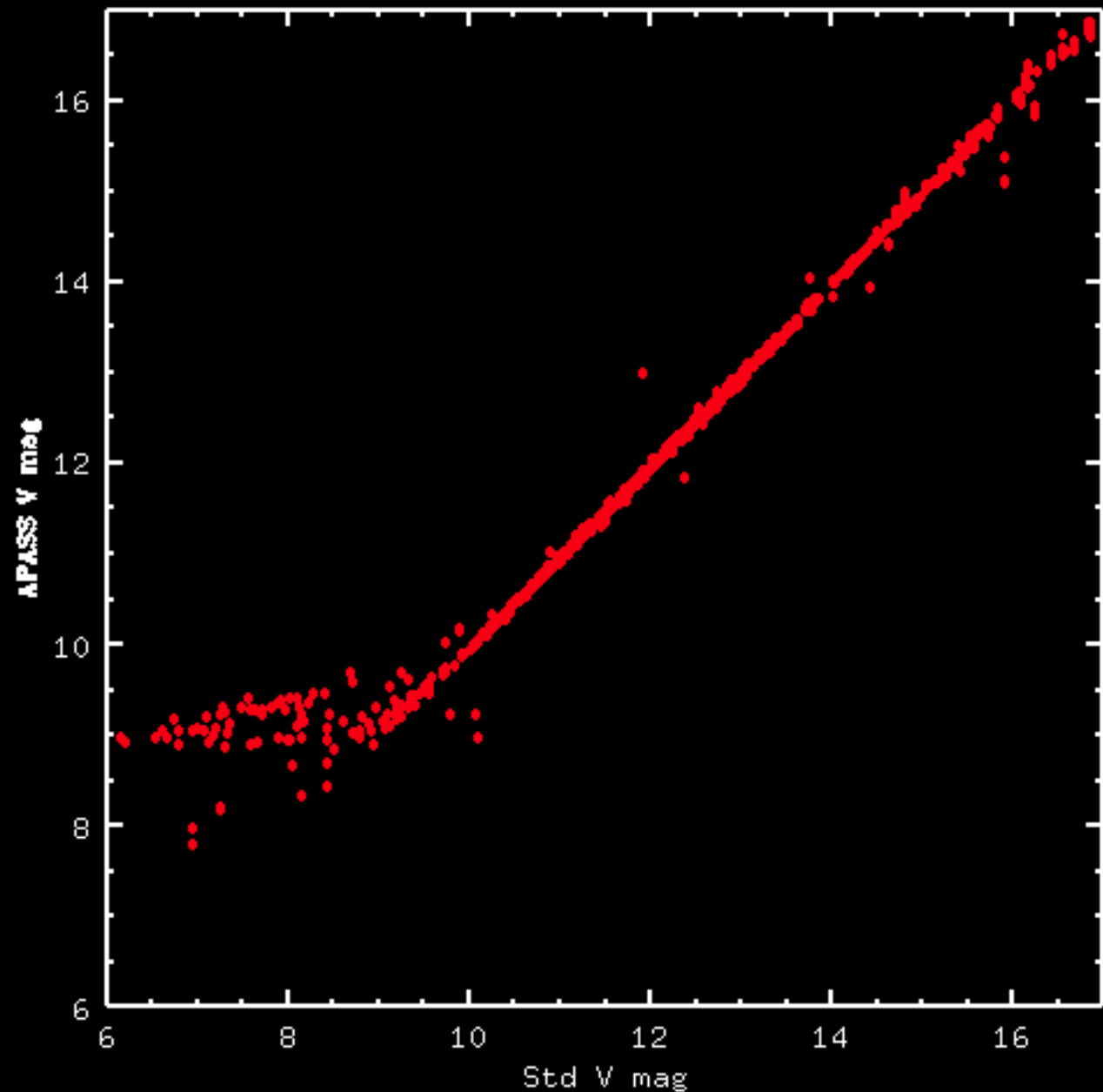
Vapass vs. Vlandolt

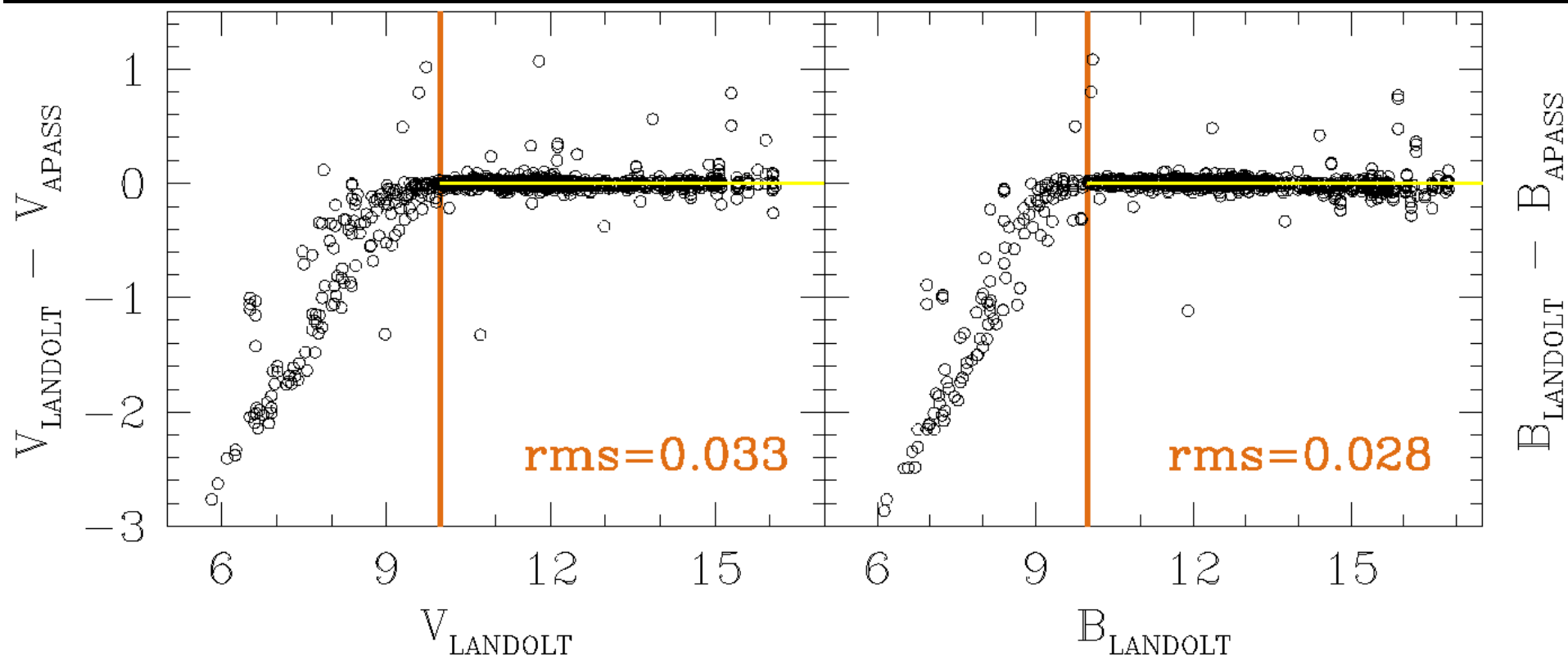
ABG means all
saturated stars
have ~same mag

Faint limit 16.5 for
Standard fields
(short exposure)

Some blends, mis-
identified stars

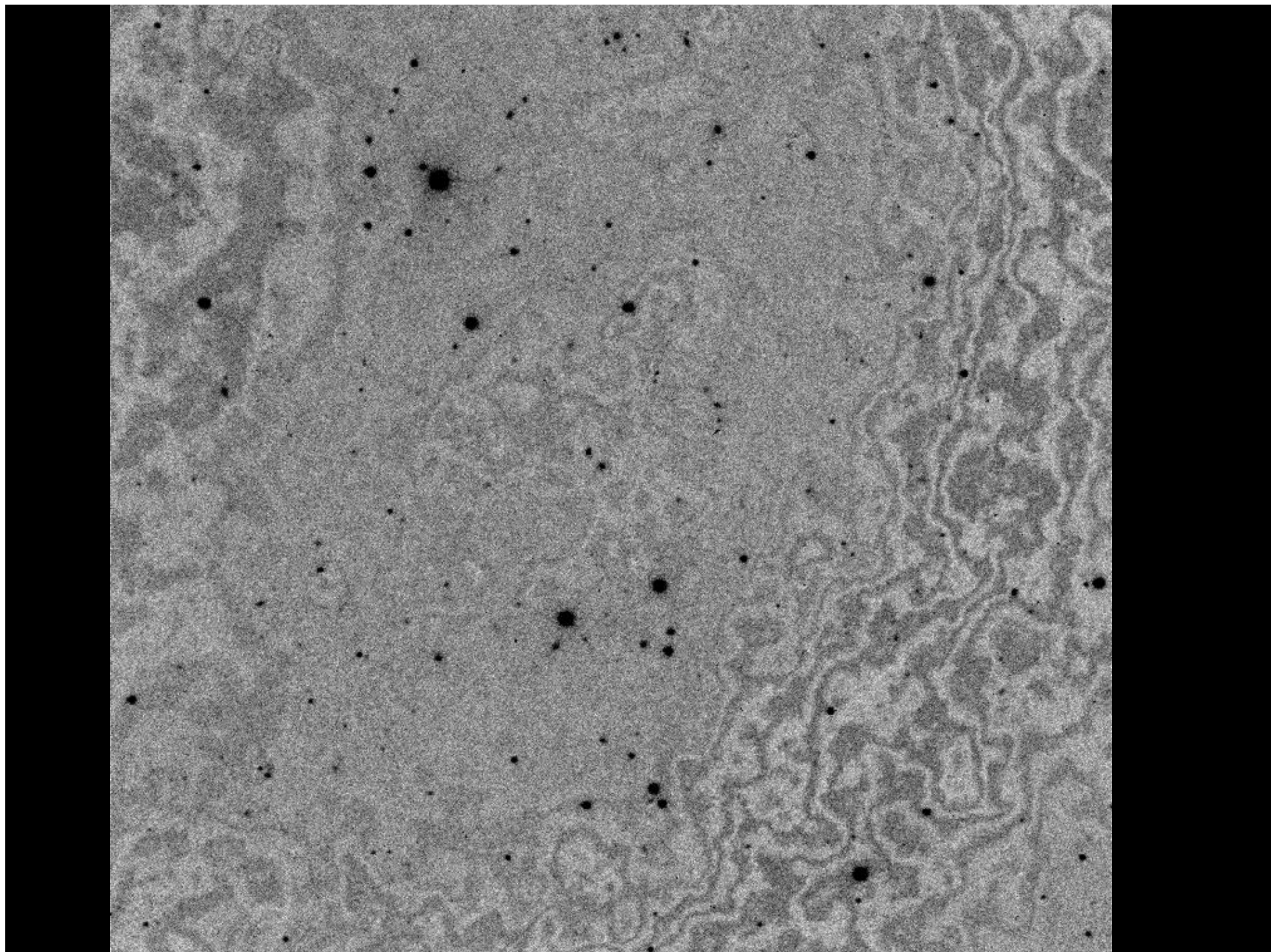
These are all
transformed
magnitudes; all
DR5 is on
standard system

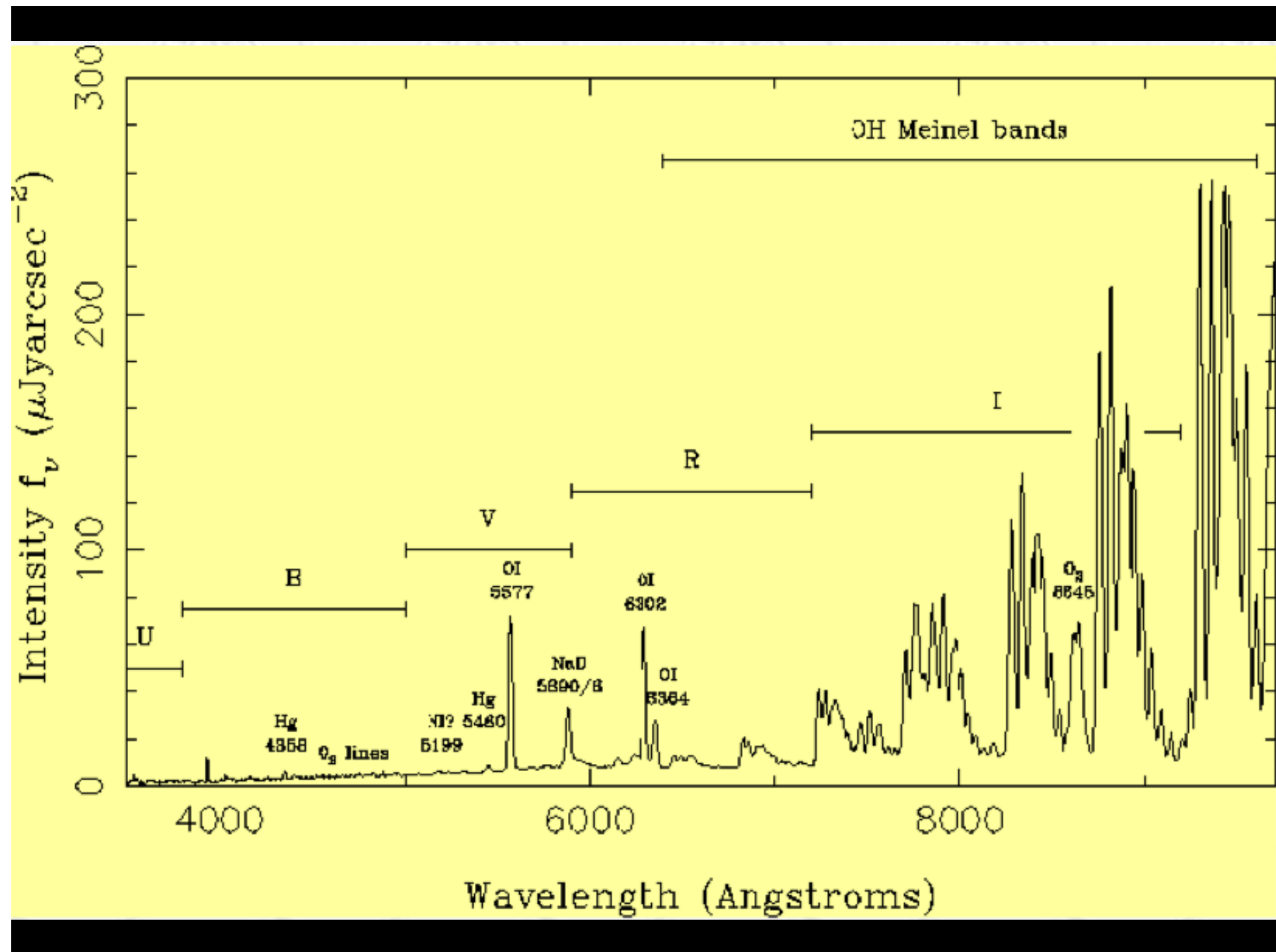




Fringing

- Due to interference effects
- Primarily seen on back-illuminated CCDs
- Primarily seen at longer wavelengths
- Night sky lines, aurora





Cosmic Rays

- Really radiation events; true cosmic rays penetrate meters of material
- Typically 200 events/cm²/hr
- Typically few pixels involved
- Can be enhanced by beta rays from high potassium glass (BK7), radioisotopes in concrete
- Non-gaussian profile, don't look like stars
- Remove by median filter or point filters

